









**DLP500YX** ZHCSKV7A - NOVEMBER 2020 - REVISED JULY 2022

# DLP500YX 0.50 2048×1200 DMD

# 1 特性

- 高分辨率 2048 × 1200 阵列
  - 大于 2.4M 微镜
  - 0.50 英寸微镜阵列对角线
  - 5.4 微米微镜间距
  - ±17.5° 微镜倾斜角(相对于平面)
  - 设计用于底部照明
  - 集成微镜驱动器电路
- 设计用于宽带可见光 (420nm 700nm)
  - 窗透射率为97%(单通,两个窗面)
  - 微镜反射率为 88%
  - 阵列衍射效率 84% (@f/2.4)
  - 阵列填充系数为 93%
- 四条 16 位低压差分信令 (LVDS)、双倍数据速率 (DDR) 输入数据总线
- 由双 DLPC900 数字控制器驱动
  - 高达 16.1kHz 1 位图形/秒
  - 在预存储图形模式下相当于 39.6 千兆位/秒像素 数据速率
  - 高达 2016Hz 8 位灰度图形速率 ( 预存储图形模 式,具有照明调制)
  - 高达 1008Hz 16 位灰度图形速率 ( 预存储图形 模式,具有照明调制)
  - 高达 247Hz 8 位图形速率(外部视频图形输 入)

### 2 应用

- 工业
  - 用于机器视觉的 3D 扫描仪
  - 3D 无接触计量和质量控制
  - 3D 打印
- 医疗
  - 眼科
  - 针对四肢和皮肤测量的 3D 扫描仪
  - 高光谱扫描和成像
- 显示器
  - 3D 成像显微镜
  - 智能和自适应照明

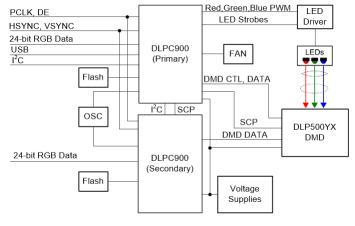
### 3 说明

DLP500YX 数字微镜器件 (DMD) 是一种空间光调制器 (SLM),调制入射光的振幅、方向和/或相位。此 DMD 与四条 2xLVDS 输入数据总线相结合,能够以超快的 图形更新速率显示高分辨率图形。DLP500YX 提供的 高分辨率和快速图形速率使其非常适合支持各种工业、 医疗和高级成像应用。DLP500YX 与双 DLPC900 数 字控制器配合使用时可实现可靠功能和操作。此专用芯 片组以满足各种终端设备解决方案要求所需的高图形速 率提供灵活且易于编程的图形流。

表 3-1. 器件信息

器件型号	封装 <sup>(1)</sup>	封装尺寸(标称值)
DLP500YX	FXK (257)	32.2mm × 22.3mm

如需了解所有可用封装,请参阅数据表末尾的可订购产品附 录。



简化版原理图



# **Table of Contents**

<b>1</b> 特性	1	7.5 Optical Interface and System Image Quality	
2 应用		Considerations	26
,		7.6 Micromirror Array Temperature Calculation	<mark>27</mark>
4 Revision History		7.7 Micromirror Landed-On/Landed-Off Duty Cycle	29
5 Pin Configuration and Functions		8 Application and Implementation	32
S Specifications		8.1 Application Information	32
6.1 Absolute Maximum Ratings		8.2 Typical Application	32
6.2 Storage Conditions		8.3 DMD Die Temperature Sensing	34
6.3 ESD Ratings		9 Power Supply Recommendations	35
6.4 Recommended Operating Conditions		9.1 DMD Power Supply Power-Up Procedure	35
6.5 Thermal Information		9.2 DMD Power Supply Power-Down Procedure	35
6.6 Electrical Characteristics		9.3 Restrictions on Hot Plugging and Hot Swapping	37
6.7 Capacitance at Recommended Operating		10 Layout	37
Conditions	15	10.1 Layout Guidelines	37
6.8 Timing Requirements		10.2 Layout Example	40
6.9 Typical Characteristics		11 Device and Documentation Support	42
6.10 System Mounting Interface Loads		11.1 第三方产品免责声明	42
6.11 Micromirror Array Physical Characteristics		11.2 Device Support	42
6.12 Micromirror Array Optical Characteristics		11.3 Documentation Support	43
6.13 Window Characteristics		11.4 接收文档更新通知	43
6.14 Chipset Component Usage Specification		11.5 支持资源	
7 Detailed Description		11.6 Trademarks	
7.1 Overview		11.7 Electrostatic Discharge Caution	
7.2 Functional Block Diagram		11.8 术语表	
7.3 Feature Description		12 Mechanical, Packaging, and Orderable	
7.4 Device Functional Modes		Information	44

# **4 Revision History**

CI	hanges from Revision * (November 2020) to Revision A (July 2022)	Page
•	This document is updated per the latest Texas Instruments and industry data sheet standards	1
•	Updated Timing Requirements	16



# **5 Pin Configuration and Functions**

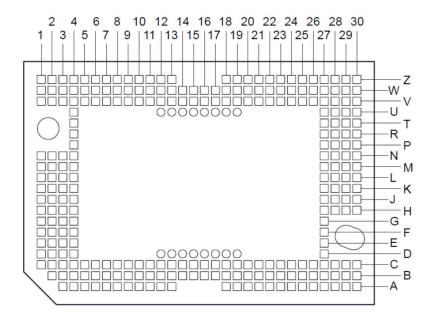


图 5-1. FXK Package 257-Pin CLGA Bottom View

#### CAUTION

To ensure reliable, long-term operation of the DLP500YX DMD, it is critical to properly manage the layout and operation of the signals identified in Pin Functions . For specific details and guidelines, refer to 节 10.1 section before designing the board.

表 5-1. Pin Functions

PIN		<b>T</b> (2)	0101141	DATA	INTERNAL	D=00DID=101/(1)	TRACE
NAME	NO.	TYPE <sup>(2)</sup>	SIGNAL RATE(6) TERMIN		TERMINATION <sup>(7)</sup>	DESCRIPTION <sup>(1)</sup>	LENGTH (mil <sup>(8)</sup> )
D_AN(0)	C6						
D_AN(1)	C3						
D_AN(2)	E1						
D_AN(3)	C4						805
D_AN(4)	D1				DDR Differential	Data negative	
D_AN(5)	B8						
D_AN(6)	F4						
D_AN(7)	E3	Input	LVDS	DDR			
D_AN(8)	C11	IIIput	LVDS				
D_AN(9)	F3						
D_AN(10)	K4						
D_AN(11)	НЗ						
D_AN(12)	J3						
D_AN(13)	C13						
D_AN(14)	A5						
D_AN(15)	A3						



PIN		(0)	7.0	DATA INTERNAL			TRACE
NAME	NO.	TYPE <sup>(2)</sup>	SIGNAL	RATE <sup>(6)</sup>	TERMINATION <sup>(7)</sup>	DESCRIPTION <sup>(1)</sup>	LENGTH (mil <sup>(8)</sup> )
D_AP(0)	C7						
D_AP(1)	C2						805
D_AP(2)	E2						
D_AP(3)	B4						
D_AP(4)	C1						
D_AP(5)	B7						
D_AP(6)	E4						
D_AP(7)	D3	Input	LVDS	DDR	Differential	Data positive	
D_AP(8)	C12	Прис	LVDS	DDK		Data positive	
D_AP(9)	F2						
D_AP(10)	J4						
D_AP(11)	G3						
D_AP(12)	J2						
D_AP(13)	C14						
D_AP(14)	A6						
D_AP(15)	A4						
D_BN(0)	N4						
D_BN(1)	Z11						
D_BN(2)	W4						
D_BN(3)	W10						
D_BN(4)	L1						
D_BN(5)	V8						
D_BN(6)	W6						
D_BN(7)	M1	Input	LVDS	DDR	Differential	Data negative	805
D_BN(8)	R4	Прис	LVDS	DDK	Dilleteritial	Data negative	803
D_BN(9)	W1						
D_BN(10)	U4						
D_BN(11)	V2						
D_BN(12)	Z5						
D_BN(13)	N3						
D_BN(14)	Z2						
D_BN(15)	L4						

#### www.ti.com.cn

PIN				DATA	INTERNAL		TRACE
NAME	NO.	TYPE <sup>(2)</sup>	SIGNAL	RATE <sup>(6)</sup>	TERMINATION(7)	DESCRIPTION <sup>(1)</sup>	LENGTH (mil <sup>(8)</sup> )
D_BP(0)	M4						805
D_BP(1)	Z12						
D_BP(2)	Z4						
D_BP(3)	Z10						
D_BP(4)	L2						
D_BP(5)	V9						
D_BP(6)	W7						
D_BP(7)	N1	Input	LVDS	DDR	Differential	Data positive	
D_BP(8)	P4	Прис	LVDS	DDK	Differential	Data positive	
D_BP(9)	V1						
D_BP(10)	T4						
D_BP(11)	V3						
D_BP(12)	Z6						
D_BP(13)	N2						
D_BP(14)	Z3						
D_BP(15)	L3						
D_CN(0)	H27						
D_CN(1)	A20						
D_CN(2)	H28						
D_CN(3)	K28						
D_CN(4)	K30						
D_CN(5)	C23						
D_CN(6)	G27						
D_CN(7)	J30	Input	LVDS	DDR	Differential	Data negative	805
D_CN(8)	B24	Input	LVDS	DDK	Dillerential	Data negative	603
D_CN(9)	A21						
D_CN(10)	A27						
D_CN(11)	C29						
D_CN(12)	A26						
D_CN(13)	C25						
D_CN(14)	A29						
D_CN(15)	C30						



PIN		(0)	TVDE(2) SIGNAL DATA		INTERNAL		TRACE
NAME	NO.	TYPE <sup>(2)</sup>	SIGNAL	RATE <sup>(6)</sup>	TERMINATION <sup>(7)</sup>	DESCRIPTION <sup>(1)</sup>	LENGTH (mil <sup>(8)</sup> )
D_CP(0)	J27						
D_CP(1)	A19						
D_CP(2)	H29						
D_CP(3)	K27						
D_CP(4)	K29						805
D_CP(5)	C22	Input					
D_CP(6)	F27						
D_CP(7)	H30		LVDS	DDR	Differential	Data positive	
D_CP(8)	B25	Input	LVDS	DDK	Differential	Data positive	
D_CP(9)	B21						
D_CP(10)	B27						
D_CP(11)	C28						
D_CP(12)	A25						
D_CP(13)	C24						
D_CP(14)	A28						
D_CP(15)	B30						
D_DN(0)	V25						
D_DN(1)	V28						
D_DN(2)	T30						
D_DN(3)	V27						
D_DN(4)	U30						
D_DN(5)	W23						
D_DN(6)	R27						
D_DN(7)	T28	Innut	LVDS	DDR	Differential		805
D_DN(8)	V20	Input	LVDS	DDR	Dillerential	Data negative	
D_DN(9)	R28						
D_DN(10)	L27						
D_DN(11)	N28						
D_DN(12)	M28						
D_DN(13)	V18	]					
D_DN(14)	Z26	]					
D_DN(15)	Z28						

PIN					nctions (continued		TRACE
NAME	NO.	TYPE <sup>(2)</sup>	SIGNAL	DATA RATE <sup>(6)</sup>	INTERNAL TERMINATION <sup>(7)</sup>	DESCRIPTION <sup>(1)</sup>	LENGTH (mil <sup>(8)</sup> )
D_DP(0)	V24						
D_DP(1)	V29	1					
D_DP(2)	T29	1					
D_DP(3)	W27	1					
D_DP(4)	V30	1					
D_DP(5)	W24	1					
D_DP(6)	T27	1					
D_DP(7)	U28		L)/DC	DDD	Differential	Dete meditive	005
D_DP(8)	V19	Input	LVDS	DDR	Differential	Data positive	805
D_DP(9)	R29	1					
D_DP(10)	M27	1					
D_DP(11)	P28	1					
D_DP(12)	M29	1					
D_DP(13)	V17	1					
D_DP(14)	Z25	1					
D_DP(15)	Z27	1					
SCTRL_AN	G1	Input	LVDS	DDR	Differential	Serial control negative <sup>(3)</sup>	805
SCTRL_AP	F1	Input	LVDS	DDR	Differential	Serial control positive <sup>(3)</sup>	805
SCTRL_BN	V5	Input	LVDS	DDR	Differential	Serial control negative <sup>(3)</sup>	805
SCTRL_BP	V4	Input	LVDS	DDR	Differential	Serial control positive <sup>(3)</sup>	805
SCTRL_CN	C26	Input	LVDS	DDR	Differential	Serial control negative <sup>(3)</sup>	805
SCTRL_CP	C27	Input	LVDS	DDR	Differential	Serial control positive <sup>(3)</sup>	805
SCTRL_DN	P30	Input	LVDS	DDR	Differential	Serial control negative <sup>(3)</sup>	805
SCTRL_DP	R30	Input	LVDS	DDR	Differential	Serial control positive <sup>(3)</sup>	805
DCLK_AN	H2	Input	LVDS		Differential	Clock negative <sup>(3)</sup>	805
DCLK_AP	H1	Input	LVDS		Differential	Clock positive <sup>(3)</sup>	805
DCLK_BN	V6	Input	LVDS		Differential	Clock negative <sup>(3)</sup>	805
DCLK_BP	V7	Input	LVDS		Differential	Clock positive <sup>(3)</sup>	805
DCLK_CN	D27	Input	LVDS		Differential	Clock negative <sup>(3)</sup>	805
DCLK_CP	E27	Input	LVDS		Differential	Clock positive <sup>(3)</sup>	805
DCLK_DN	N29	Input	LVDS		Differential	Clock negative <sup>(3)</sup>	805
DCLK_DP	N30	Input	LVDS		Differential	Clock positive <sup>(3)</sup>	805
SCPCLK	A10	Input	LVCMOS		Pull down	Serial communications port clock. Active only when SCPENZ is logic low <sup>(3)</sup>	
SCPDI	A12	Input	LVCMOS	SDR	Pull down	Serial communications port data input. Synchronous to SCPCLK rising edge <sup>(3)</sup>	
SCPENZ	C10	Input	LVCMOS		Pull down	Serial communications port enable active low <sup>(3)</sup>	
SCPDO	A11	Output	LVCMOS	SDR		Serial communications port output	



PIN			A 5-1. PIN Functions (continued		4)	TRACE	
NAME	NO.	TYPE <sup>(2)</sup>	SIGNAL	RATE <sup>(6)</sup>	TERMINATION(7)	DESCRIPTION <sup>(1)</sup>	LENGTH (mil <sup>(8)</sup> )
RESET_ADDR(	Z13						
0) RESET_ADDR(							
1) W13		Input	LVCMOS		Pull down	Reset driver address select <sup>(3)</sup>	
RESET_ADDR( 2)	V10		2.00				
RESET_ADDR( 3)	W14						
RESET_MOD E(0)	W9					Reset driver mode select <sup>(3)</sup>	
RESET_SEL(0)	V14	Input	LVCMOS		Pull down	Reset driver level select <sup>(3)</sup>	
RESET_SEL(1)	Z8					Reset driver level select.(3)	
RESET_STRO BE	<b>Z</b> 9	Input	LVCMOS		Pull down	Rising edge latches in RESET_ADDR, RESET_MODE, & RESET_SEL.(3)	
PWRDNZ	A8	Input	LVCMOS		Pull down	Active low device reset.(3)	
RESET_OEZ	W15	Input	LVCMOS		Pull up	Active low output enable for internal reset driver circuits. (3)	
RESET_IRQZ	V16	Output	LVCMOS			Active low output interrupt to DLP controller	
EN_OFFSET	C9	Output	LVCMOS			Active high enable for external V <sub>OFFSET</sub> regulator	
PG_OFFSET	A9	Input	LVCMOS		Pull up	Active low fault from external V <sub>OFFSET</sub> regulator <sup>(3)</sup>	
TEMP_N	B18	Input	Analog			Temperature sensor diode cathode	
TEMP_P	B17	Input	Analog			Temperature sensor diode anode	
RESERVED **MUST VERIFY WITH SRC DATA SHEET	D12, D13, D14, D15, D16, D17, D18, D19, U12, U13, U14, U15	NC	Analog		Pull Down  Do not connect on DLF board. No connect. No connections from CMC pad to package pin.		
No Connect	U16, U17, U18, U19	NC				No connect. No electrical connection from CMOS bond pad to package pin	
RESERVED_B A	W11						
RESERVED_B B	B11	Outpost	LVCMOS			Do not connect on DLP system	
RESERVED_B C	Z20	Output	LVCIVIOS			board.	
RESERVED_B	C18						
RESERVED_P FE	A18	Incut	LVCMOS		Dull down	Do not connect on DLP system	
RESERVED_T	C8	Input	LVCMOS		Pull down	board.	

www.ti.com.cn

PIN			<del>\( \) \( \) \</del>	i. Fili i ui	ictions (continued		TRACE
		TYPE(2)	SIGNAL	DATA INTERNAL DESCR		DESCRIPTION <sup>(1)</sup>	LENGTH
NAME	NO.		0.0	RATE <sup>(6)</sup>	TERMINATION <sup>(7)</sup>	5=00111111011	(mil <sup>(8)</sup> )
RESERVED_T P0	Z19						
RESERVED_T P1	W20	Input	Analog			Do not connect on DLP system board.	
RESERVED_T P2	W19						
V <sub>BIAS</sub> <sup>(4)</sup>	C15, C16, V11, V12	Power	Analog			Supply voltage for positive bias level of micromirror reset signal	
V <sub>RESET</sub> (4)	G4, H4, J1, K1	Power	Analog			Supply voltage for negative reset level of micromirror reset signal	
V <sub>OFFSET</sub> (4)	A30, B2, M30, Z1, Z30	Power	Analog			Supply voltage for HVCMOS logic. Supply voltage for positive offset level of micromirror reset signal. Supply voltage for stepped high voltage at micromirror address electrodes	
Vcc <sup>(4)</sup>	A24, A7, B10, B13, B16, B19, B22, B28, B5, C17, C20, D4, J29, K2, L29, M2, N27, V13, V15, V22, W17, W21, W26, W29, W3, Z18, Z23, Z29, Z7	Power	Analog			Supply voltage for LVCMOS core. Supply voltage for positive offset level of micromirror reset signal during power down. Supply voltage for normal high level at micromirror address electrodes	



PIN		(2)		DATA	INTERNAL	(1)	TRACE
NAME	NO.	TYPE <sup>(2)</sup>	SIGNAL	RATE <sup>(6)</sup>	TERMINATION <sup>(7)</sup>	DESCRIPTION <sup>(1)</sup>	LENGTH (mil <sup>(8)</sup> )
V <sub>SS</sub> <sup>(5)</sup>	A13, A22, A23, B12, B14, B15, B20, B23, B26, B29, B3, B6, B9, C19, C21, C5, D2, G2, J28, K3, L28, L30, M3, P27, P29, V21, V23, V26, W12, W16, W18, W2, W22, W25, W28, W30, W5, W8, Z21, Z22, Z24	Ground				Device ground. Common return for all power.	

- (1) The DLP500YX DMD is a component of a DLP chipset. Reliable function and operation of the DLP500YX DMD requires that it be used in conjunction with the other components of the applicable DLP chipset, including those components that contain or implement TI DMD control technology. TI DMD control technology is the TI technology and devices for operating or controlling a DLP DMD.
- (2) I = Input, O = Output, P = Power, G = Ground, NC = No connect
- (3) These signals are very sensitive to noise or intermittent power connections, which can cause irreversible DMD micromirror array damage or, to a lesser extent, image disruption. Consider this precaution during DMD board design and manufacturer handling of the DMD sub-assemblies.
- (4) The following power supplies are required to operate the DMD: V<sub>CC</sub>, V<sub>OFFSET</sub>, V<sub>BIAS</sub>, and V<sub>RESET</sub>.
- (5) V<sub>SS</sub> must be connected for proper DMD operation.
- (6) DDR = Double Data Rate, SDR = Single Data Rate. Refer to the Timing Requirements for specifications and relationships.
- (7) Internal term = CMOS level internal termination. Refer to Recommended Operating Conditions for differential termination specification.
- (8) Dielectric Constant for the DMD FXK (S410) ceramic package is approximately 9.6. For the package trace lengths shown: Propagation Speed = 11.8 sqrt (9.60 = 3.808 in/ns. Propagation Delay = 0.262 ns/in = 262 ps/in = 10.315 ps/mm.



# 6 Specifications

# 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

		MIN	MAX	UNIT
SUPPLY VOLTAGES				
V <sub>CC</sub>	Supply voltage for LVCMOS core logic <sup>(2)</sup>	- 0.5	2.3	V
V <sub>OFFSET</sub>	Supply voltage for HVCMOS and micromirror electrode <sup>(2)</sup> (3)	- 0.5	11	V
V <sub>BIAS</sub>	Supply voltage for micromirror electrode <sup>(2)</sup>	- 0.5	19	V
V <sub>RESET</sub>	Supply voltage for micromirror electrode <sup>(2)</sup>	- 15	- 0.3	V
V <sub>BIAS</sub> - V <sub>OFFSET</sub>	Supply voltage difference (absolute value) <sup>(4)</sup>		11	V
V <sub>BIAS</sub> - V <sub>RESET</sub>	Supply voltage difference (absolute value) <sup>(5)</sup>		34	V
INPUT VOLTAGES				
	Input voltage for all other LVCMOS input pins <sup>(2)</sup>	- 0.5	V <sub>CC</sub> + 0.5	V
	Input voltage for all other LVDS input pins (2) (6)	- 0.5	V <sub>CC</sub> + 0.5	V
V <sub>ID</sub>	Input differential voltage (absolute value) <sup>(7)</sup>		500	mV
I <sub>ID</sub>	Input differential current <sup>(6)</sup>		6.3	mA
CLOCKS				
$f_{CLOCK}$	Clock frequency for LVDS interface, DCLK_A, DCLK_B, DCLK_C, DCLK_D		400	MHz
ENVIRONMENTAL				
T and T	Array temperature: operational <sup>(8)</sup>	0	90	°C
T <sub>ARRAY</sub> and T <sub>WINDOW</sub>	Array temperature: non - operational <sup>(8)</sup>	- 40	90	°C
T <sub>DELTA</sub>	Absolute temperature delta between any point on the window edge and the ceramic test point TP1 <sup>(9)</sup>		30	°C
T <sub>DP</sub>	Dew point temperature, operating and non - operating (non-condensing)		81	°C

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) All voltages are referenced to common ground V<sub>SS</sub>. V<sub>BIAS</sub>, V<sub>CC</sub>, V<sub>OFFSET</sub>, and V<sub>RESET</sub> power supplies are all required for proper DMD operation. V<sub>SS</sub> must also be connected.
- (3) V<sub>OFFSET</sub> supply transients must fall within specified voltages.
- (4) Exceeding the recommended allowable voltage difference between V<sub>BIAS</sub> and V<sub>OFFSET</sub> may result in excessive current draw.
- (5) Exceeding the recommended allowable voltage difference between V<sub>BIAS</sub> and V<sub>RESET</sub> may result in excessive current draw.
- (6) LVDS differential inputs must not exceed the specified limit or damage may result to the internal termination resistors.
- (7) This maximum LVDS input voltage rating applies when each input of a differential pair is at the same voltage potential.
- (8) The highest temperature of the active array (as calculated using #7.6) or of any location along the window edge as defined in 🖺 7-2. The locations of thermal test points TP2, TP3, TP4, and TP5 in 🖺 7-2 are intended to measure the highest window edge temperature. If a particular application causes another location on the window edge to be at a higher temperature, use that location.
- (9) Temperature delta is the highest difference between the ceramic test point 1 (TP1) and anywhere on the window edge as shown in Section 7-2. The window test points TP2, TP3, TP4, and TP5 shown in Section 7-2 are intended to result in the worst case delta. If a particular application causes another location on the window edge to result in a larger delta temperature, use that location.

Copyright © 2022 Texas Instruments Incorporated



# **6.2 Storage Conditions**

Applicable for the DMD as a component or non-operating in a system.

		MIN	MAX	UNIT
$T_{DMD}$	DMD storage temperature	- 40	80	°C
T <sub>DP-AVG</sub>	Average dew point temperature (non-condensing) (1)		28	°C
T <sub>DP-ELR</sub>	Elevated dew point temperature range (non-condensing) (2)	28	36	°C
CT <sub>ELR</sub>	Cumulative time in elevated dew point temperature range		24	Months

- (1) The average over time (including storage and operating) that the device is not in the elevated dew point temperature range.
- (2) Limit the exposure to dew point temperatures in the elevated range during storage and operation to less than a total cumulative time of CT<sub>ELR</sub>.

# 6.3 ESD Ratings

				VALUE	UNIT
	V <sub>(ESD)</sub> Electrostatic discharge	Electrostatic	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000	V
		discharge Charged device model (CDM), per JEDEC specification JESD22-C10	Charged device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±500	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

# **6.4 Recommended Operating Conditions**

Over operating free-air temperature range (unless otherwise noted). The functional performance of the device specified in this data sheet is achieved when operating the device within the limits defined by this table. No level of performance is implied when operating the device above or below these limits.

		MIN	NOM	MAX	UNIT
VOLTAGE SUPPLY					
V <sub>CC</sub>	LVCMOS logic supply voltage <sup>(1)</sup>	1.65	1.8	1.95	V
V <sub>OFFSET</sub>	Mirror electrode and HVCMOS voltage <sup>(1)</sup> (2)	9.5	10	10.5	V
V <sub>BIAS</sub>	Mirror electrode voltage <sup>(1)</sup>	17.5	18	18.5	V
V <sub>RESET</sub>	Mirror electrode voltage <sup>(1)</sup>	- 14.5	- 14	- 13.5	V
V <sub>BIAS</sub> - V <sub>OFFSET</sub>	Supply voltage difference (absolute value) <sup>(3)</sup>			10.5	V
V <sub>BIAS</sub> - V <sub>RESET</sub>	Supply voltage difference (absolute value) <sup>(4)</sup>			33	V
LVCMOS INTERFACE					
V <sub>IH(DC)</sub>	DC input high voltage <sup>(5)</sup>	0.7 × V <sub>CC</sub>		V <sub>CC</sub> + 0.3	V
V <sub>IL(DC)</sub>	DC input low voltage <sup>(5)</sup>	- 0.3		0.3 × V <sub>CC</sub>	V
V <sub>IH(AC)</sub>	AC input high voltage <sup>(5)</sup>	0.8 × V <sub>CC</sub>		V <sub>CC</sub> + 0.3	V
V <sub>IL(AC)</sub>	AC input low voltage <sup>(5)</sup>	- 0.3		0.2 × V <sub>CC</sub>	V
t <sub>PWRDNZ</sub>	PWRDNZ pulse duration <sup>(6)</sup>	10			ns
SCP INTERFACE				<u>'</u>	
$f_{\sf SCPCLK}$	SCP clock frequency <sup>(7)</sup>			500	kHz
t <sub>SCP_PD</sub>	Propagation delay, clock to Q, from rising-edge of SCPCLK to valid $\mbox{SCPDO}^{(8)}$	0		900	ns
t <sub>SCP_NEG_ENZ</sub>	Time between falling-edge of SCPENZ and the first rising-edge of SCPCLK	1			μs
t <sub>SCP_POS_ENZ</sub>	Time between falling-edge of SCPCLK and the rising-edge of SCPENZ	1			μs
t <sub>SCP_DS</sub>	SCPDI clock setup time (before SCPCLK falling edge) <sup>(8)</sup>	800			ns
t <sub>SCP_DH</sub>	SCPDI hold time (after SCPCLK falling edge) <sup>(8)</sup>	900			ns
t <sub>SCP_PW_ENZ</sub>	SCPENZ inactive pulse duration (high level)	2			μs
LVDS INTERFACE					

Submit Document Feedback

Copyright © 2022 Texas Instruments Incorporated

# 6.4 Recommended Operating Conditions (continued)

Over operating free-air temperature range (unless otherwise noted). The functional performance of the device specified in this data sheet is achieved when operating the device within the limits defined by this table. No level of performance is implied when operating the device above or below these limits.

		MIN	NOM	MAX	UNIT
$f_{CLOCK}$	Clock frequency for LVDS interface (all channels), DCLK <sup>(9)</sup>			400	MHz
V <sub>ID</sub>	Input differential voltage (absolute value) <sup>(10)</sup>	150	300	440	mV
V <sub>CM</sub>	Common mode voltage <sup>(10)</sup>	1100	1200	1300	mV
V <sub>LVDS</sub>	LVDS voltage <sup>(10)</sup>	880		1520	mV
t <sub>LVDS_RSTZ</sub>	Time required for LVDS receivers to recover from PWRDNZ			2000	ns
Z <sub>IN</sub>	Internal differential termination resistance	80	100	120	Ω
Z <sub>LINE</sub>	Line differential impedance (PWB/trace)	90	100	110	Ω
ENVIRONMENTAL					
<b>-</b>	Array temperature, long - term operational(11) (12) (13) (14)	10		40 to 70 <sup>(13)</sup>	°C
T <sub>ARRAY</sub>	Array temperature, short - term operational <sup>(12)</sup> (15)	0		10	°C
T <sub>WINDOW</sub>	Window temperature - operational <sup>(16)</sup>	,		85	°C
T <sub>DELTA</sub>	Absolute temperature delta between any point on the window edge and the ceramic test point TP1 <sup>(16)</sup> (17)			14	°C
T <sub>DP-AVG</sub>	Average dew point temperature (non-condensing) <sup>(18)</sup>			28	°C
T <sub>DP-ELR</sub>	Elevated dew point temperature range (non-condensing) <sup>(19)</sup>	28		36	°C
CT <sub>ELR</sub>	Cumulative time in elevated dew point temperature range			24	Months
ILL <sub>0</sub>	Illumination marginal ray angle <sup>(20)</sup>			55	deg
For Illumination Sou	urce Between 420 nm and 700 nm				
ILL <sub>VIS</sub>	Illumination power density on array <sup>(21)</sup>			31	W/cm <sup>2</sup>
ILL <sub>VISTP</sub>	Illumination total power on array			22	W
For Illumination Sou	urce <420 nm and >700 nm				
ILL <sub>IR</sub>	Illumination wavelengths > 700 nm			10	mW/cm <sup>2</sup>
ILL <sub>UV</sub>	Illumination wavelengths < 420 nm <sup>(11)</sup>			10	mW/cm <sup>2</sup>

- All voltages are referenced to common ground V<sub>SS</sub>. V<sub>BIAS</sub>, V<sub>CC</sub>, V<sub>OFFSET</sub>, and V<sub>RESET</sub> power supplies are all required for proper DMD operation. V<sub>SS</sub> must also be connected.
- (2) V<sub>OFFSET</sub> supply transients must fall within specified max voltages.
- (3) To prevent excess current, the supply voltage difference |V<sub>BIAS</sub> V<sub>OFFSET</sub>| must be less than the specified limit. See 节 9,图 9-1, and 表 9-1.
- (4) To prevent excess current, the supply voltage difference |V<sub>BIAS</sub> V<sub>RESET</sub>| must be less than the specified limit. See 节 9,图 9-1, and 表 9-1.
- (5) Low-speed interface is LPSDR and adheres to the Electrical Characteristics and AC/DC Operating Conditions table in JEDEC Standard No. 209B, "Low-Power Double Data Rate (LPDDR)" JESD209B. Tester conditions for V<sub>IH</sub> and V<sub>IL</sub>.
  - Frequency = 60 MHz. Maximum rise time = 2.5 ns at 20/80
  - Frequency = 60 MHz. Maximum fall time = 2.5 ns at 80/20
- (6) PWRDNZ input pin resets the SCP and disables the LVDS receivers. PWRDNZ input pin overrides SCPENZ input pin and tristates the SCPDO output pin.
- (7) The SCP clock is a gated clock. Duty cycle must be 50% ± 10%. SCP parameter is related to the frequency of DCLK.
- (8) See 🖺 6-2.
- (9) See LVDS timing requirements in 节 6.8 and 图 6-6.
- (10) See LVDS waveform requirements in \( \begin{array}{c} \) 6-5.
- (11) Simultaneous exposure of the DMD to the maximum # 6.4 for temperature and UV illumination reduces device lifetime.
- (12) The array temperature cannot be measured directly and must be computed analytically from the temperature measured at test point 1 (TP1) shown in 图 7-2 and the package thermal resistance 节 7.6.
- (13) Per 🛮 6-1, the maximum operational array temperature must be derated based on the micromirror landed duty cycle that the DMD experiences in the end application. See 🕆 7.7 for a definition of micromirror landed duty cycle.
- (14) Long-term is defined as the usable life of the device.
- (15) Array temperatures beyond those specified as long-term are recommended for short-term conditions only (power-up). Short-term is defined as the cumulative time over the usable life of the device and is less than 500 hours.

Copyright © 2022 Texas Instruments Incorporated



- (16) Temperature delta is the highest difference between the ceramic test point 1 (TP1) and anywhere on the window edge as shown in 3 7-2. The window test points TP2, TP3, TP4, and TP5 shown in 3 7-2 are intended to result in the worst case delta temperature. If a particular application causes another location on the window edge to result in a larger delta in temperature, use that location.
- (17) DMD is qualified at the maximum temperature specified. Operation of the DMD outside of these limits has not been tested.
- (18) The average over time (including storage and operating) that the device is not in the elevated dew point temperature range.
- (19) Limit exposure to dew point temperatures in the elevated range during storage and operation to less than a total cumulative time of CT<sub>FI R</sub>.
- (20) The maximum marginal ray angle of the incoming illumination light at any point in the micromirror array, including the pond of micromirrors (POM), cannot exceed 55 degrees from the normal to the device array plane. The device window aperture has not necessarily been designed to allow incoming light at higher maximum angles to pass to the micromirrors, and the device performance has not been tested nor qualified at angles exceeding this. Illumination light exceeding this angle outside the micromirror array (including POM) contributes to thermal limitations described in this document, and may negatively affect lifetime.
- (21) The maximum optical power that can be incident on the DMD is limited by the maximum optical power density and the micromirror array temperature.

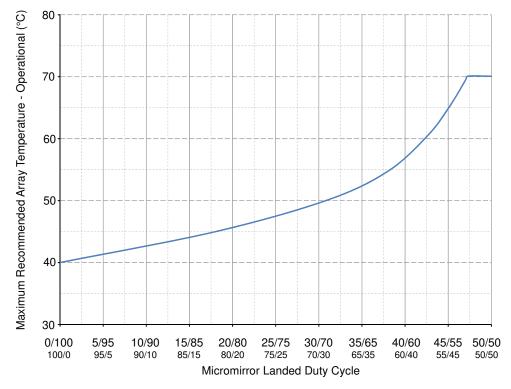


图 6-1. Maximum Recommended Array Temperature—Derating Curve

#### 6.5 Thermal Information

	DLP500YX	
THERMAL METRIC	FXK Package	UNIT
	257 PINS	
Thermal resistance, active area to test point 1 (TP1) <sup>(1)</sup>	0.90	°C/W

(1) The DMD is designed to conduct absorbed and dissipated heat to the back of the package. The cooling system must be capable of maintaining the package within the temperature range specified in the # 6.4.

The total heat load on the DMD is largely driven by the incident light absorbed by the active area; although other contributions include light energy absorbed by the window aperture and electrical power dissipation of the array.

Optical systems must be designed to minimize the light energy falling outside the window clear aperture since any additional thermal load in this area can significantly degrade the reliability of the device.



### 6.6 Electrical Characteristics

Over operating free-air temperature range (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	MIN	TYP MAX	UNIT
OUTPUT VO	LTAGES			'	
V <sub>OH</sub>	High level output voltage	$V_{CC}$ = 1.8 V, $I_{OH}$ = -2 mA	0.8 x V <sub>CC</sub>		V
V <sub>OL</sub>	Low level output voltage	V <sub>CC</sub> = 1.95 V, I <sub>OL</sub> = 2 mA		0.2 x V <sub>CC</sub>	V
CURRENTS					
l <sub>oz</sub>	High impedance output current	V <sub>CC</sub> = 1.95 V	- 40	25	μΑ
I <sub>IL</sub>	Low level input current	V <sub>CC</sub> = 1.95 V, V <sub>I</sub> = 0	- 1		μΑ
I <sub>IH</sub>	High level input current (1)	V <sub>CC</sub> = 1.95 V, V <sub>I</sub> = V <sub>CC</sub>		110	μA
I <sub>CC</sub>	Supply current V <sub>CC</sub>	V <sub>CC</sub> = 1.95 V		1500	mA
I <sub>OFFSET</sub>	Supply current V <sub>OFFSET</sub> (2)	V <sub>OFFSET</sub> = 10.5 V		13	mA
I <sub>BIAS</sub>	Supply current V <sub>BIAS</sub> (2) (3)	V <sub>BIAS</sub> = 18.5 V		4	mA
I <sub>RESET</sub>	Supply current V <sub>RESET</sub> (3)	V <sub>RESET</sub> = - 14.5 V		- 9	mA
SUPPLY PO	WER				
P <sub>CC</sub>	Supply power dissipation V <sub>CC</sub>	V <sub>CC</sub> = 1.95 V		2925	mW
P <sub>OFFSET</sub>	Supply power dissipation V <sub>OFFSET</sub> (2)	V <sub>OFFSET</sub> = 10.5 V		139	mW
P <sub>BIAS</sub>	Supply power dissipation V <sub>BIAS</sub> (2) (3)	V <sub>BIAS</sub> = 18.5 V		67	mW
P <sub>RESET</sub>	Supply power dissipation V <sub>RESET</sub> <sup>(3)</sup>	V <sub>RESET</sub> = -14.5 V		131	mW
P <sub>TOTAL</sub>	Supply power dissipation V <sub>TOTAL</sub>			3261	mW

- (1) Applies to LVCMOS pins only. Excludes LVDS pins and MBRST (15:0) pins.
- (2) To prevent excess current, the supply voltage difference |V<sub>BIAS</sub> V<sub>OFFSET</sub>| must be less than the specified limits listed in the #6.4 table.
- (3) To prevent excess current, the supply voltage difference  $|V_{BIAS} V_{RESET}|$  must be less than specified limit in # 6.4.

### 6.7 Capacitance at Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted).

	1 0 1	,				
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
C <sub>I_lvds</sub>	LVDS input capacitance 2xLVDS	f = 1 MHz			20	pF
C <sub>I_nonlvds</sub>	Non-LVDS input capacitance	f = 1 MHz			20	pF
C <sub>I_tdiode</sub>	Temperature diode input capacitance	f = 1 MHz			30	pF
Co	Output capacitance	f = 1 MHz			20	pF



# 6.8 Timing Requirements

			MIN	NOM	MAX	UNIT
SCP IN	TERFACE <sup>(1)</sup>					
t <sub>r</sub>	Rise time	20% to 80% reference points	1		3	V/ns
t <sub>f</sub>	Fall time	80% to 20% reference points	1		3	V/ns
LVDS I	NTERFACE <sup>(2)</sup>					
t <sub>r</sub>	Rise slew rate	20% to 80% reference points	0.7	1		V/ns
t <sub>f</sub>	Fall slew rate	80% to 20% reference points	0.7	1		V/ns
		DCLK_A, LVDS pair	2.5			ns
	Ola ala avala	DCLK_B, LVDS pair	2.5			ns
t <sub>C</sub>	Clock cycle	DCLK_C, LVDS pair	2.5			ns
		DCLK_D, LVDS pair	2.5			ns
		DCLK_A, LVDS pair	1.19	1.25		ns
t <sub>W</sub>	Pulse duration	DCLK_B, LVDS pair	1.19	1.25		ns
		DCLK_C, LVDS pair	1.19	1.25		ns
		DCLK_D, LVDS pair	1.19	1.25		ns
		D_A(15:0) before DCLK_A, LVDS pair	0.275			ns
		D_B(15:0) before DCLK_B, LVDS pair	0.275			ns
		D_C(15:0) before DCLK_C, LVDS pair	0.275			ns
	Catum times	D_D(15:0) before DCLK_D, LVDS pair	0.275			ns
t <sub>Su</sub>	Setup time	SCTRL_A before DCLK_A, LVDS pair	0.275			ns
		SCTRL_B before DCLK_B, LVDS pair	0.275			ns
		SCTRL_C before DCLK_C, LVDS pair	0.275			ns
		SCTRL_D before DCLK_D, LVDS pair	0.275			ns
		D_A(15:0) after DCLK_A, LVDS pair	0.195			ns
		D_B(15:0) after DCLK_B, LVDS pair	0.195			ns
		D_C(15:0) after DCLK_C, LVDS pair	0.195			ns
	I I a I al Airea a	D_D(15:0) after DCLK_D, LVDS pair	0.195			ns
t <sub>h</sub>	Hold time	SCTRL_A after DCLK_A, LVDS pair	0.195			ns
		SCTRL_B after DCLK_B, LVDS pair	0.195			ns
		SCTRL_C after DCLK_C, LVDS pair	0.195			ns
		SCTRL_D after DCLK_D, LVDS pair	0.195			ns
t <sub>SKEW</sub>	Skew time	Channel B relative to channel A (3) (4)	- 1.25		1.25	ns
t <sub>SKEW</sub>	Skew time	Channel D relative to channel C <sup>(5)</sup> (6), LVDS pair	- 1.25		1.25	ns

- (1) See 图 6-3 for rise time and fall time for SCP.
- (2) See 图 6-5 for timing requirements for LVDS.
- (3) Channel A (Bus A) includes the following LVDS pairs: DCLK\_AN and DCLK\_AP, SCTRL\_AN and SCTRL\_AP, D\_AN(15:0) and D\_AP(15:0).
- (4) Channel B (Bus B) includes the following LVDS pairs: DCLK\_BN and DCLK\_BP, SCTRL\_BN and SCTRL\_BP, D\_BN(15:0) and D\_BP(15:0).
- (5) Channel C (Bus C) includes the following LVDS pairs: DCLK\_CN and DCLK\_CP, SCTRL\_CN and SCTRL\_CP, D\_CN(15:0) and D\_CP(15:0).
- (6) Channel D (Bus D) includes the following LVDS pairs: DCLK\_DN and DCLK\_DP, SCTRL\_DN and SCTRL\_DP, D\_DN(15:0) and D\_DP(15:0).

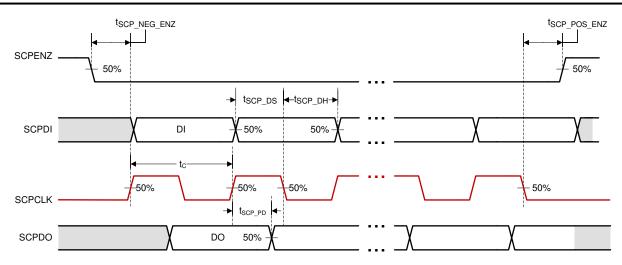


图 6-2. SCP Timing Requirements

- A. See  $\ddagger$  6.4 for f<sub>SCPCLK</sub>, t<sub>SCP\_DS</sub>, t<sub>SCP\_DH</sub> and t<sub>SCP\_PD</sub> specifications.
- B. SCPCLK falling edge capture for SCPDI.
- C. SCPCLK rising edge launch for SCPDO.
- D. See 方程式 1

$$f_{SCPCLK} = \frac{1}{t_C}$$

(1)

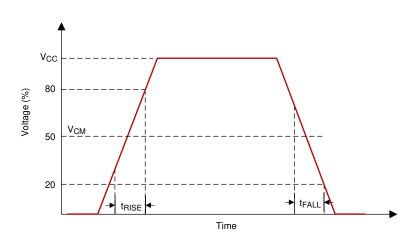


图 6-3. SCP Requirements for Rise and Fall

See  $\ddagger$  6.8 for  $t_r$  and  $t_f$  specifications and conditions.

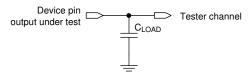
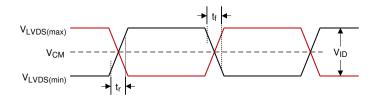


图 6-4. Test Load Circuit for Output Propagation Measurement

(3)

For output timing analysis, the tester pin electronics and its transmission line effects must be taken into account. System designers must use IBIS or other simulation tools to correlate the timing reference load to a system environment.



#### A. See 方程式 2 and 方程式 3

#### 图 6-5. LVDS Waveform Requirements

$$V_{LVDS (max)} = V_{CM (max)} + \left| \frac{1}{2} \times V_{ID (max)} \right|$$
(2)

$$V_{LVDS (min)} = V_{CM (min)} - \left| \frac{1}{2} \times V_{ID (max)} \right|$$

See  $\ddagger$  6.4 for  $V_{CM}$ ,  $V_{ID}$ , and  $V_{LVDS}$  specifications and conditions.

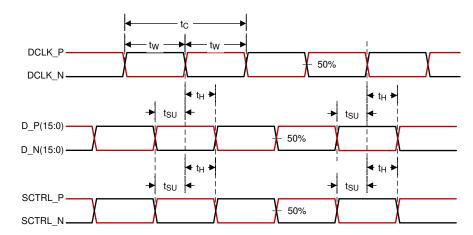


图 6-6. Timing Requirements

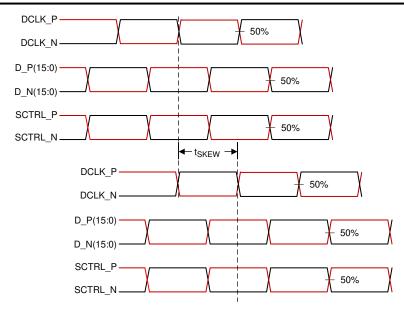


图 6-7. LVDS Interface Channel Skew Definition

See † 6.8 for timing requirements and LVDS pairs per channel (bus) defining D\_P(15:0) and D\_N(15:0).

# **6.9 Typical Characteristics**

When the DMD is controlled by the DLPC900, the digital controller has four modes of operation:

- A. Video mode
- B. Video pattern mode
- C. Pre-stored pattern mode
- D. Pattern on-the-fly mode

In video mode (A), the 24-bit frames displayed on the DMD are the same as the input 24-bit video frame rates. In video pattern mode (B), the  $V_{SYNC}$  rates displayed on the DMD are linked to the incoming video source  $V_{SYNC}$  rates but the overall pattern rates depend upon the configured bit depth. In modes B, C, and D, the pattern rates depend on the bit depth as shown in  $\frac{1}{8}$  6-1.

表 6-1. DLP500YX Pattern Rate versus Bit Depth using DLPC900

BIT DEPTH	VIDEO PATTERN MODE (Hz)	PRE-STORED or PATTERN ON-THE-FLY MODE (Hz)
1	2880	16129
2	1440	5434
3	960	3717
4	720	2183
5	480	1466
6	480	1239
7	360	923
8	247	441
10		96
12		24
14		6
16		1

Copyright © 2022 Texas Instruments Incorporated

Submit Document Feedback



# 6.10 System Mounting Interface Loads

表 6-2. System Mounting Interface Loads

A D I System mounting interface Education							
MIN	NOM	MAX	UNIT				
		111	N				
		111	N				
		222	N				
		0	N				
			MIN NOM MAX  111 111				

(1) Apply the load uniformly in the corresponding areas shown in 图 6-8.

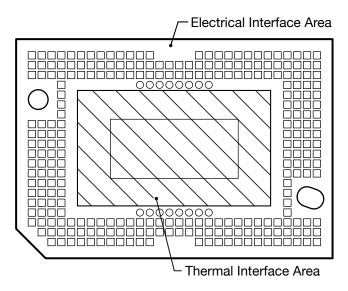


图 6-8. System Mounting Interface Loads

# **6.11 Micromirror Array Physical Characteristics**

表 6-3. Micromirror Array Physical Characteristics

PARAMETER DESCRIPTION			UNIT
Number of active columns <sup>(1)</sup>	M	2048	micromirrors
Number of active rows <sup>(1)</sup>	N	1200	micromirrors
Micromirror (pixel) pitch <sup>(1)</sup>	P	5.4	μm
Micromirror active array width <sup>(1)</sup>	Micromirror Pitch × number of active columns	11.0592	mm
Micromirror active array height <sup>(1)</sup>	Micromirror Pitch × number of active rows	6.4800	mm
Micromirror active border (All four sides) (2)	Pond of micromirrors (POM)	20	micromirrors/side

<sup>(1)</sup> See \( \bigsize 6-9 \)

Product Folder Links: DLP500YX

The structure and qualities of the border around the active array includes a band of partially functional micromirrors referred to as the pond of micromirrors (POM). These micromirrors are structurally and/or electrically prevented from tilting toward the bright or ON state but still require an electrical bias to tilt toward the OFF state.



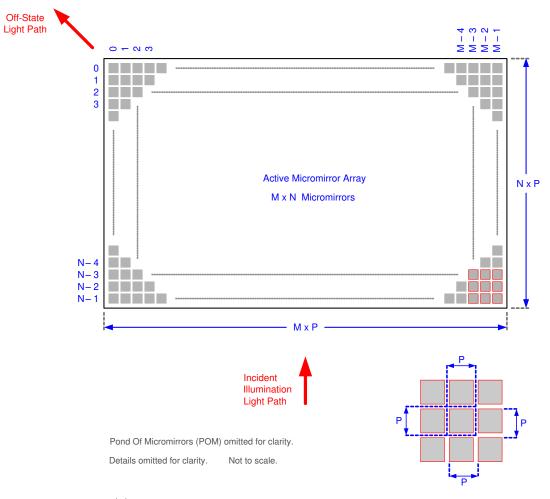


图 6-9. Micromirror Array Physical Characteristics

Refer to † 6.11 table for M, N, and P specifications.



#### 6.12 Micromirror Array Optical Characteristics

#### 表 6-4. Micromirror Array Optical Characteristics

PARAMETER	TEST CONDITION	MIN	NOM	MAX	UNIT
Mirror tilt angle (1) (2) (3) (4)	Landed State	15.6	17.5	18.4	degrees
Micromirror crossover time <sup>(5)</sup>	Typical Performance		1	3	116
Micromirror switching time <sup>(6)</sup>	Typical Performance	6			μs
Number of out-of-specification	Adjacent micromirrors			0	micromirrors
micromirrors <sup>(7)</sup>	Non-Adjacent micromirrors			10	TillCromittors
DMD Photopic Efficiency <sup>(8)</sup>	420 - 700 nm		65%		

- (1) Measured relative to the plane formed by the overall micromirror array
- (2) Represents the variation that can occur between any two individual micromirrors, located on the same device or located on different devices.
- (3) For some applications, it is critical to account for the micromirror tilt angle variation in the overall system optical design. With some system optical designs, the micromirror tilt angle variation within a device may result in perceivable non-uniformities in the light field reflected from the micromirror array. With some system optical designs, the micromirror tilt angle variation between devices may result in colorimetry variations, system efficiency variations or system contrast variations.
- (4) When the micromirror array is landed (not parked), the tilt direction of each individual micromirror is dictated by the binary contents of the CMOS memory cell associated with each individual micromirror. A binary value of 1 results in a micromirror landing in the ON State direction. A binary value of 0 results in a micromirror landing in the OFF State direction. See [8] 6-10.
- (5) The time required for a micromirror to nominally transition from one landed state to the opposite landed state.
- (6) The minimum time between successive transitions of a micromirror.
- (7) An out-of-specification micromirror is defined as a micromirror that is unable to transition between the two landed states within the specified MICROMIRROR SWITCHING Time.
- (8) Efficiency numbers assume 35-degree illumination angle, F/2.4 illumination and collection cones, uniform source spectrum, and uniform pupil illumination.
  - Window Transmission 94% (double Pass, Through Two Window Surfaces)
  - · Micromirror Reflectivity 88%
  - Array Diffraction Efficiency 84% (@f/2.4)
  - Array Fill Factor 93%

Efficiency numbers assume 100% electronic mirror duty cycle and do not include optical overfill loss. Note that this number is specified under conditions described above and deviations from the specified conditions could result in decreased efficiency.

Product Folder Links: DLP500YX



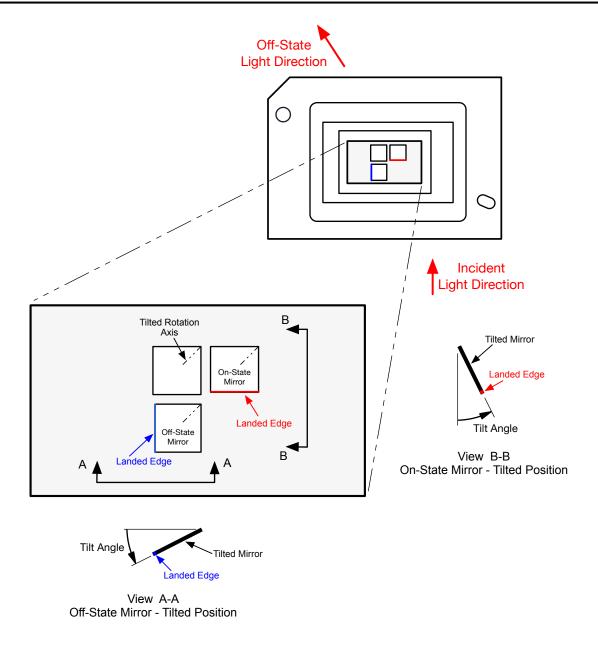


图 6-10. Micromirror Landed Orientation and Tilt



#### 6.13 Window Characteristics

#### 表 6-5. DMD Window Characteristics

PARAMETER <sup>(1)</sup>	CONDITIONS	MIN	NOM	MAX	UNIT
Window material	Corning Eagle XG				
Window refractive index	at wavelength 546.1 nm		1.5119		
Window aperture	See Note (2)				
Illumination overfill	Refer to # 7.5.3				
Window transmittance, single - pass through both surfaces and glass <sup>(3)</sup>	Minimum within the wavelength range 420 nm to 680 nm. Applies to all angles 0° to 30° AOI.	97%			
	Average over the wavelength range 420 nm to 680 nm. Applies to all angles 30° to 45° AOI.	97%			

- (1) See #7.5 for more information.
- (2) For details on the size and location of the window aperture, see the Mechanical ICD in the Mechanical, Packaging, and Orderable Information section of this data sheet.
- (3) See the TI application report DLPA031, Wavelength Transmittance Considerations for DLP® DMD Window.

#### **6.14 Chipset Component Usage Specification**

Reliable function and operation of the DLP500YX DMD requires that it be used in conjunction with the other components of the applicable DLP chipset, including those components that contain or implement TI DMD control technology. TI DMD control technology consists of the TI technology and devices used for operating or controlling a DLP DMD.

omit Document Feedback

Product Folder Links: DLP500YX

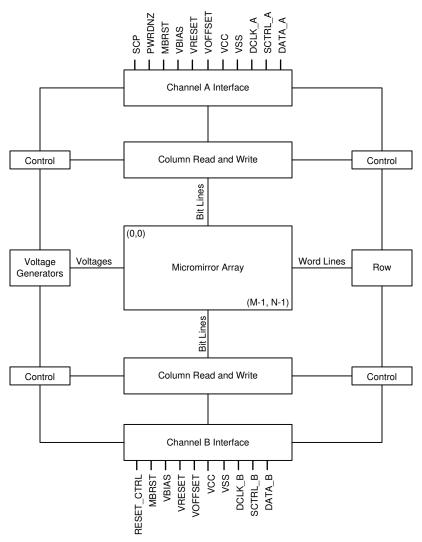
# 7 Detailed Description

### 7.1 Overview

The DLP500YX DMD is a 0.50-inch diagonal spatial light modulator which consists of an array of highly reflective aluminum micromirrors. The DMD is an electrical input, optical output micro-electrical-mechanical system (MEMS). The electrical interface is low voltage differential signaling (LVDS). The DMD consists of a two-dimensional array of 1-bit CMOS memory cells. The array is organized in a grid of M memory cell columns by N memory cell rows. Refer to † 7.2 . The positive or negative deflection angle of the micromirrors can be individually controlled by changing the address voltage of underlying CMOS addressing circuitry and micromirror reset signals (MBRST).

The DMD is one part of a chipset comprising of the DLP500YX DMD and the DLPC900 Controller. To ensure reliable operation, the DLPC900 Controller must always be used to control the DLP500YX DMD.

#### 7.2 Functional Block Diagram



Channels C and D not shown. For pin details on channels A, B, C, and D, refer to the *Pin Configurations and Functions* table and the LVDS interface section of # 6.8.

图 7-1. Functional Block Diagram



#### 7.3 Feature Description

#### 7.3.1 Power Interface

The DMD requires 5 DC voltages: DMD\_P3P3V, DMD\_P1P8V, VOFFSET, VRESET, and VBIAS. DMD\_P3P3V is a filtered version of the 3.3VDS supply received over the flex cables from the DLPC910 Controller Board. DMD P3P3V is used on the DMD Board to create the other DMD voltages (DMD P1P8V, VOFFSET, VRESET, and VBIAS) required for proper DMD operation. TI provides a DMD board reference design on TI.com to enable customers to see how these voltages are created as well and how the DMD board design is accomplished.

#### **7.3.2 Timing**

The data sheet provides timing at the device pin. For output timing analysis, the tester pin electronics and its transmission line effects must be taken into account. 8 6-4 shows an equivalent test load circuit for the output under test. Timing reference loads are not intended as a precise representation of any particular system environment or depiction of the actual load presented by a production test. System designers need to use IBIS or other simulation tools to correlate the timing reference load to a system environment. The load capacitance value stated is only for characterization and measurement of AC timing signals. This load capacitance value does not indicate the maximum load the device is capable of driving.

#### 7.4 Device Functional Modes

DMD functional modes are controlled by the DLPC900 controller. See the DLPC900 controller data sheet or contact a TI applications engineer.

#### 7.5 Optical Interface and System Image Quality Considerations

备注

TI assumes no responsibility for image quality artifacts or DMD failures caused by optical system operating conditions exceeding limits described previously.

TI assumes no responsibility for end-equipment optical performance. Achieving the desired end-equipment optical performance involves making trade-offs between numerous component and system design parameters. Optimizing system optical performance and image quality strongly relate to optical system design parameter trades. Although it is not possible to anticipate every conceivable application, the projected image quality and the optical performance are contingent on compliance to the optical system operating conditions described in the following sections.

#### 7.5.1 Numerical Aperture and Stray Light Control

The angle defined by the numerical aperture of the illumination and projection optics at the DMD optical area needs to be the same. This angle cannot exceed the nominal device micromirror tilt angle unless appropriate apertures are added in the illumination and/or projection pupils to block out flat-state and stray light from the projection lens. The micromirror tilt angle defines DMD capability to separate the "ON" optical path from any other light path, including undesirable flat-state specular reflections from the DMD window, DMD border structures, or other system surfaces near the DMD such as prism or lens surfaces. If the numerical aperture exceeds the micromirror tilt angle, or if the projection numerical aperture angle is more than two degrees larger than the illumination numerical aperture angle (and vice versa), contrast degradation, and objectionable artifacts in the display border and/or active area could occur.

#### 7.5.2 Pupil Match

TI's optical and image quality specifications assume that the exit pupil of the illumination optics is nominally centered within 2° of the entrance pupil of the projection optics. Misalignment of pupils can create objectionable artifacts in the display border or active area, which may require additional system apertures to control, especially if the numerical aperture of the system exceeds the pixel tilt angle.

#### 7.5.3 Illumination Overfill

The active area of the device is surrounded by an aperture on the inside DMD window surface that masks structures of the DMD chip assembly from normal view, and is sized to anticipate several optical operating

Product Folder Links: DLP500YX

Submit Document Feedback

conditions. Overfill light illuminating the window aperture can create artifacts from the edge of the window aperture opening and other surface anomalies that may be visible on the screen. Design the illumination optical system to limit light flux incident anywhere on the window aperture from exceeding approximately 10% of the average flux level in the active area. Depending on the particular system optical architecture, overfill light may have to be further reduced below the suggested 10% level in order to be acceptable.

# 7.6 Micromirror Array Temperature Calculation

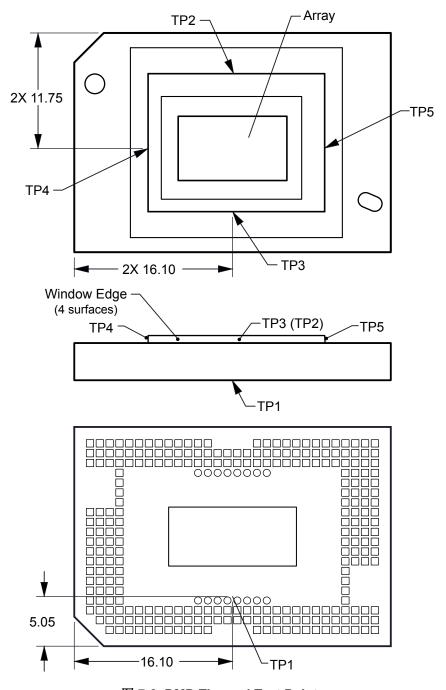


图 7-2. DMD Thermal Test Points



Micromirror array temperature can be computed analytically from measurement points on the outside of the package, the package thermal resistance, the electrical power, and the illumination heat load. The relationship between micromirror array temperature and the reference ceramic temperature is provided by the following equations:

$$T_{ARRAY} = T_{CERAMIC} + (Q_{ARRAY} \times R_{ARRAY-TO-CERAMIC})$$

$$Q_{ARRAY} = Q_{ELECTRICAL} + Q_{ILLUMINATION}$$

#### where

- T<sub>ARRAY</sub> = Computed array temperature (°C)
- T<sub>CERAMIC</sub> = Measured ceramic temperature (°C) (measured at TP1 location)
- R<sub>ARRAY-TO-CERAMIC</sub> = Thermal resistance of package specified in Thermal Information from array to ceramic TP1 (°C/Watt)
- Q<sub>ARRAY</sub> = Total DMD power on the array (W) (electrical + absorbed)
- Q<sub>ELECTRICAL</sub> = Nominal electrical power (W)
- Q<sub>ILLUMINATION</sub> = Illumination power absorbed (W)

The electrical power dissipation of the DMD is variable and depends on the voltages, data rates, and operating frequencies. A nominal electrical power dissipation to use when calculating array temperature is 3.26 W. The absorbed power from the illumination source is variable and depends on the operating state of the micromirrors and the intensity of the light source. The factors used in determining the illumination power absorbed is shown in each of the examples below. Examples are included where the optical power has been determined by measuring the illumination power density, total illumination power, and screen lumens. The examples assume illumination distribution is 83.7% on the active array and 16.3% on the area outside the array.

#### 7.6.1 Micromirror Array Temperature Calculation using Illumination Power Density

The equations below are valid for each DMD in a single chip or multi-chip DMD system.

- Q<sub>ILLUMINATION</sub> = (Q<sub>INCIDENT</sub> × DMD average thermal absorptivity) (W)
- Q<sub>INCIDENT</sub> = ILL<sub>DENSITY</sub> × ILL<sub>AREA</sub> (W)
- ILL<sub>DENSITY</sub> = measured illumination optical power density at DMD (W/cm<sup>2</sup>)
- ILL<sub>ARFA</sub> = illumination area on DMD (cm<sup>2</sup>)
- DMD average thermal absorptivity = 0.40

```
Q_{ELECTRICAL} = 3.26 \text{ W}
Array \text{ size} = 11.0592 \text{ mm} \times 6.4800 \text{ mm} = 0.72 \text{ cm}^2
ILL_{DENSITY} = 31 \text{ W/cm}^2 \text{ (measured)}
T_{CERAMIC} = 50.0 \text{ °C (measured)}
ILL_{AREA} = 0.72 \text{ cm}^2 / (83.7\%) = 0.86 \text{ cm}^2
Q_{INCIDENT} = 31 \text{ W/cm}^2 \times 0.86 \text{ cm}^2 = 26.66 \text{ W}
Q_{ARRAY} = 3.26 \text{ W} + (0.40 \times 26.66 \text{ W}) = 13.92 \text{ W}
T_{ARRAY} = 50.0 \text{ °C} + (13.92 \text{ W} \times 0.90 \text{ °C/W}) = 62.53 \text{ °C}
```

#### 7.6.2 Micromirror Array Temperature Calculation using Total Illumination Power

The equations below are valid for each DMD in a single chip or multi-chip DMD system.

Q<sub>ILLUMINATION</sub> = (Q<sub>INCIDENT</sub> × DMD average thermal absorptivity) (W)



#### www.ti.com.cn

- Q<sub>INCIDENT</sub> = measured total illumination optical power at DMD (W)
- DMD average thermal absorptivity = 0.40

```
Q<sub>ELECTRICAL</sub> = 3.26 W
Q<sub>INCIDENT</sub> =26.66 W (measured)
T<sub>CFRAMIC</sub> = 50.0 °C (measured)
Q_{ARRAY} = 3.26 \text{ W} + (0.40 \times 26.66 \text{ W}) = 13.92 \text{ W}
T_{ARRAY} = 50.0 \text{ °C} + (13.92 \text{ W} \times 0.90 \text{ °C/W}) = 62.53 \text{ °C}
```

### 7.6.3 Micromirror Array Temperature Calculation using Screen Lumens

The equations below are valid for a single chip DMD system with spectral efficiency of 300 lumens/Watt.

- $Q_{ILLUMINATION} = SL \times C_{L2W}(W)$
- SL = measured ANSI screen lumens (Im)
- C<sub>I 2W</sub> = Conversion constant for screen lumens to power absorbed on DMD (Watts/Lumen)

```
Q<sub>ELECTRICAL</sub> = 3.26 W
C_{L2W} = 0.00266 \text{ W/lm}
SL = 4000 lm (measured)
T<sub>CFRAMIC</sub> = 50.0 °C (measured)
Q_{ARRAY} = 3.26 \text{ W} + (0.00266 \text{ W/lm} \times 4000 \text{ lm}) = 13.9 \text{ W}
T_{ARRAY} = 50.0 \, ^{\circ}\text{C} + (13.9 \, \text{W} \times 0.90 \, ^{\circ}\text{C/W}) = 62.51 \, ^{\circ}\text{C}
```

### 7.7 Micromirror Landed-On/Landed-Off Duty Cycle

#### 7.7.1 Definition of Micromirror Landed-On/Landed-Off Duty Cycle

The micromirror landed-on/landed-off duty cycle (landed duty cycle) denotes the amount of time (as a percentage) that an individual micromirror is landed in the ON state versus the amount of time the same micromirror is landed in the OFF state.

As an example, a landed duty cycle of 100/0 indicates that the referenced pixel is in the ON state 100% of the time (and in the OFF state 0% of the time), whereas 0/100 would indicate that the pixel is in the OFF state 100% of the time. Likewise, 50/50 indicates that the pixel is ON for 50% of the time (and OFF for 50% of the time).

Note that when assessing the landed duty cycle, the time spent switching from one state (ON or OFF) to the other state (OFF or ON) is considered negligible and is thus ignored.

Since a micromirror can only be landed in one state or the other (ON or OFF), the two numbers (percentages) always add to 100.



#### 7.7.2 Landed Duty Cycle and Useful Life of the DMD

Knowing the long-term average landed duty cycle (of the end product or application) is important because subjecting all (or a portion) of the DMD micromirror array (also called the active array) to an asymmetric landed duty cycle for a prolonged period of time can reduce the DMD usable life.

Note that it is the symmetry or asymmetry of the landed duty cycle that is of relevance. The symmetry of the landed duty cycle is determined by how close the two numbers (percentages) are to being equal. For example, a landed duty cycle of 50/50 is perfectly symmetrical whereas a landed duty cycle of 100/0 or 0/100 is perfectly asymmetrical.

#### 7.7.3 Landed Duty Cycle and Operational DMD Temperature

Operational DMD temperature and landed duty cycle interact to affect DMD usable life, and this interaction can be exploited to reduce the impact that an asymmetrical landed duty cycle has on the DMD usable life. This is quantified in the de-rating curve shown in 

8 6-1. The importance of this curve is that:

- · All points along this curve represent the same usable life.
- All points above this curve represent lower usable life (and the further away from the curve, the lower the usable life).
- All points below this curve represent higher usable life (and the further away from the curve, the higher the usable life).

In practice, this curve specifies the maximum operating DMD temperature at a given long-term average landed duty cycle.

#### 7.7.4 Estimating the Long-Term Average Landed Duty Cycle of a Product or Application

During a given period of time, the landed duty cycle of a given pixel follows from the image content being displayed by that pixel.

For example, in the simplest case, when displaying pure-white on a given pixel for a given time period, that pixel operates under a 100/0 landed duty cycle during that time period. Likewise, when displaying pure-black, the pixel operates under a 0/100 landed duty cycle.

If the use case involves inputting Grayscale input images, between the two extremes (ignoring for the moment color), the Landed Duty Cycle tracks one-to-one with the gray scale value, as shown in  $\frac{1}{2}$  7-1.

表 7-1. Grayscale Value and Landed Duty Cycle

GRAYSCALE VALUE	LANDED DUTY CYCLE
0%	0/100
10%	10/90
20%	20/80
30%	30/70
40%	40/60
50%	50/50
60%	60/40
70%	70/30
80%	80/20
90%	90/10
100%	100/0

Product Folder Links: DI P500YX

Accounting for color rendition (but still ignoring image processing) requires knowing both the color intensity (from 0% to 100%) for each constituent primary color (red, green, or blue) for the given pixel as well as the color cycle time for each primary color, where "color cycle time" is the total percentage of the frame time that a given primary must be displayed in order to achieve the desired white point.

Use the following equation to calculate the landed duty cycle of a given pixel during a specified time period

Landed Duty Cycle = (Red\_Cycle\_% × Red\_Scale\_Value) + (Green\_Cycle\_% × Green\_Scale\_Value) + (Blue\_Cycle\_% × Blue\_Scale\_Value)

#### where

- Red\_Cycle\_% represents the percentage of the frame time that red is displayed to achieve the desired white
  point
- Green\_Cycle\_% represents the percentage of the frame time that green is displayed to achieve the desired white point
- Blue\_Cycle\_% represents the percentage of the frame time that blue is displayed to achieve the desired white point

For example, assume that the red, green, and blue color cycle times are 50%, 20%, and 30% respectively (in order to achieve the desired white point), then the landed duty cycle for various combinations of red, green, and blue color intensities would be as shown in  $\frac{1}{8}$  7-2 and  $\frac{1}{8}$  7-3.

表 7-2. Example Landed Duty Cycle for Full-Color, Color Percentage

CYCLE PERCENTAGE				
RED	GREEN	BLUE		
50%	20%	30%		

表 7-3. Example Landed Duty Cycle for Full-Color

SCALE VALUE			LANDED DUTY	
RED	GREEN	BLUE	CYCLE	
0%	0%	0%	0/100	
100%	0%	0%	50/50	
0%	100%	0%	20/80	
0%	0%	100%	30/70	
12%	0%	0%	6/94	
0%	35%	0%	7/93	
0%	0%	60%	18/82	
100%	100%	0%	70/30	
0%	100%	100%	50/50	
100%	0%	100%	80/20	
12%	35%	0%	13/87	
0%	35%	60%	25/75	
12%	0%	60%	24/76	
100%	100%	100%	100/0	

Copyright © 2022 Texas Instruments Incorporated

Submit Document Feedback



# 8 Application and Implementation

#### 备注

以下应用部分中的信息不属于 TI 器件规格的范围, TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计,以确保系统功能。

### **8.1 Application Information**

The DMD is a spatial light modulator, which reflects incoming light from an illumination source to one of two directions, with the primary direction being into a projection or collection optic. Each application is derived primarily from the optical architecture of the system and the format of the data being used.

The DLP500YX DMD is controlled by two DLPC900 controllers. The DMD itself receives bit planes through a 2xLVDS input data bus and, when input control commands dictate, activates the controls which update the mechanical state of the DMD mirrors. In combination with the DLPC900 Controllers, the chipset enables four unique modes of system level operation:

- Video Mode 24 bit video signals presented to inputs of the DLPC900 Controllers appear on the DMD. The DMD mirrors are updated in a PWM fashion to construct the 24 bit video data. This mode is similar to standard DLP Display projector use cases.
- Video Pattern Mode the user can define periods of time for specific patterns to be displayed on the DMD. Those patterns are provided via the input video interface and are constrained to input video timing parameters. This mode is optimal for when the data to be presented is not known in advance of operation, or input data needs to be streamed or updated based on real-time processing conditions.
- Pre-stored Pattern Mode the user can define the patterns in advance and build the pattern data into an onboard flash memory. Upon power up, the DLPC900 controllers immediately start reading and displaying those patterns. This mode is typically used in applications where the patterns to be used are known in advance and the patterns can all fit in the external flash memory. This mode typically provides the fastest pattern update rates.
- Pattern-on-the-Fly Pattern Mode the user can download and update pattern data over the DLPC900 input USB data interface. This allows an external processor to modify and update patterns based on external processing decisions. This mode also provides streaming capability similar to the Video Pattern Mode except that the user would need to take into account delays involved with USB transmission of pattern data and control information.

The DLP500YX provides solutions for many varied applications including structured light (3-D machine vision), 3-D printing, information projection, and lithography.

The DLP500YX contains the most recent breakthrough micromirror technology called the TRP pixel. With a smaller pixel pitch of  $5.4~\mu$  m and increased tilt angle of 17 degrees, TRP chipsets enable higher resolution in a smaller form factor while maintaining high optical efficiency. DLP chipsets are a great fit for any system that requires high resolution and high output projection imaging.

#### 8.2 Typical Application

3D machine vision is a typical embedded system application for the DLP500YX DMD. In this application, two DLPC900 devices control the pattern data being imaged from a DLP500YX DMD onto the object being measured while an external camera system monitors the projected patterns as they appear on the object. An external microprocessor can then geometrically determine all 3D points of the object using the knowledge of the projected pattern provided to the object, the actual distorted pattern as captured by the camera, and the angle between the projector line-of-sight and the camera line-of-sight. This type of application diagram is shown in 8-1. In this configuration, the DLPC900 controller supports a 24-bit parallel RGB video input from an external source computer or processor. The video input FPGA splits each 2048 x 1200 image frame into a left half and a right half with the left half feeding the Primary DLPC900 and the right half feeding the Secondary DLPC900. Each half consists of 1024 columns by 1200 rows plus any horizontal and vertical blanking at half the pixel clock rate. This system configuration supports still and motion video as well as sequential pattern modes. For more

Product Folder Links: DI P500YX

information, refer to the DLPC900 digital controller data sheet, found on the DLPC900 Product Folder listed under 节 11.3.1.

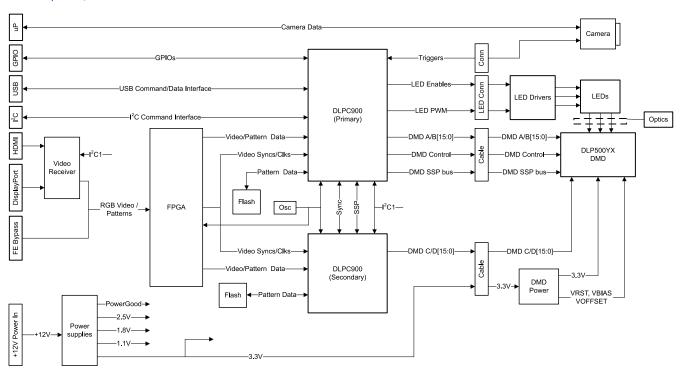


图 8-1. Typical DLP500YX Application Diagram

#### 8.2.1 Design Requirements

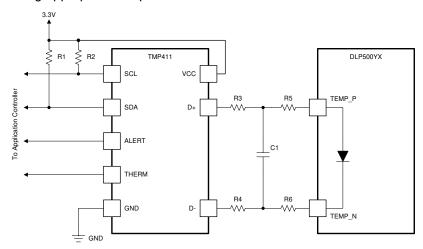
At the high level, typical DLP500YX DMD systems include an illumination source (Lamp, LED, or Laser), an optical light engine containing both illumination and projection optics, mechanics, electronic components, power supplies, cooling systems, and software. The designer must first choose an illumination source and design the optical engine taking into consideration the optical relationship from the illumination source to the DMD, and from the DMD to the location of the projected image. The designer must then understand the electronic components of a DLP500YX DMD system, part of which includes one or more PCBs which contain the DMD and Controllers. In the TI DLP500YX based evaluation module design, the DLPC900 Controller board provides power, bit plane data, and control information to the DMD mounted on the DLP500YX DMD board. The DLPC900 Controller board also interfaces to the user system, accepting image data based on user provided timing (software or hardware triggered) and providing that data in bit plane format to the DMD to be projected on the imaging target.

#### 8.2.2 Detailed Design Procedure

A TI evaluation module design exists which shows how to connect the DLPC900 controller to the DMD. In creating a new board specific to a customer application, layout guidelines need to be followed to achieve a functional and reliable projection system. To complete the system, an optical module or light engine is required that contains the DLP500YX DMD, associated illumination sources, optical elements, and necessary mechanical components. Care must be taken to understand and implement wise design decisions regarding the engineering aspects of illumination and projection optics, digital and analog electronics, software, and mechanical and thermal design principles.

### 8.3 DMD Die Temperature Sensing

The DMD features a built-in thermal diode that measures the temperature at one corner of the die outside the micromirror array. The DMD thermal diode pins B17 and B18 can be connected to the TMP411 temperature sensor as shown in 8-2, and an external processor can interface with the TMP411 temperature sensor over l²C bus to allow monitoring of the DMD temperature. This temperature data can be leveraged to incorporate additional functionality in the overall system design such as adjusting illumination, fan speeds, and so forth, all with the idea of maintaining appropriate temperature control of the DMD.



- A. Details omitted for clarity, see the DLPLCR500YXEVM evaluation module design for connections.
- B. See the TMP411 datasheet for system board layout recommendation.
- C. See the TMP411 datasheet and the DLPLCR500YXEVM evaluation module design for suggested component values for R1, R2, R3, R4, and C1.
- D. R5 = 0  $\Omega$ . R6 = 0  $\Omega$ . Zero ohm resistors need to be located close to the DMD package pins.

图 8-2. TMP411 Sample Schematic



# 9 Power Supply Recommendations

The following power supplies are all required to operate the DMD:

- V<sub>SS</sub>
- V<sub>BIAS</sub>
- V<sub>CC</sub>
- V<sub>OFFSET</sub>
- V<sub>RESET</sub>

DMD power-up and power-down sequencing is strictly controlled by the DLP® controller.

#### **CAUTION**

For reliable operation of the DMD, the following power supply sequencing requirements must be followed. Failure to adhere to any of the prescribed power-up and power-down requirements may affect device reliability. See 

9-1.

 $V_{BIAS}$ ,  $V_{CC}$ ,  $V_{OFFSET}$ , and  $V_{RESET}$  power supplies must be coordinated during power-up and power-down operations. Failure to meet any of the below requirements results in a significant reduction in the DMD reliability and lifetime. Common ground  $V_{SS}$  must also be connected.

#### 9.1 DMD Power Supply Power-Up Procedure

- During power-up, V<sub>CC</sub> must always start and settle before V<sub>OFFSET</sub> plus Delay1 specified in 表 9-1, V<sub>BIAS</sub>, and V<sub>RESET</sub> voltages are applied to the DMD.
- During power-up, it is a strict requirement that the voltage difference between V<sub>BIAS</sub> and V<sub>OFFSET</sub> must be within the specified limit shown in † 6.4.
- During power-up, there is no requirement for the relative timing of V<sub>RESET</sub> with respect to V<sub>BIAS</sub>.
- Power supply slew rates during power-up are flexible, provided that the transient voltage levels follow the requirements specified in 节 6.1, in 节 6.4, and in 图 9-1.
- During power-up, LVCMOS input pins must not be driven high until after V<sub>CC</sub> have settled at operating voltages listed in <sup>††</sup> 6.4.

#### 9.2 DMD Power Supply Power-Down Procedure

- During power-down, V<sub>CC</sub> must be supplied until after V<sub>BIAS</sub>, V<sub>RESET</sub>, and V<sub>OFFSET</sub> are discharged to within the specified limit of ground. See 表 9-1.
- During power-down, it is a strict requirement that the voltage difference between V<sub>BIAS</sub> and V<sub>OFFSET</sub> must be within the specified limit shown in <sup>†</sup> 6.4.
- During power-down, there is no requirement for the relative timing of V<sub>RESET</sub> with respect to V<sub>BIAS</sub>.
- Power supply slew rates during power-down are flexible, provided that the transient voltage levels follow the requirements specified in 节 6.1, in 节 6.4, and in 图 9-1.
- During power-down, LVCMOS input pins must be less than specified in † 6.4.



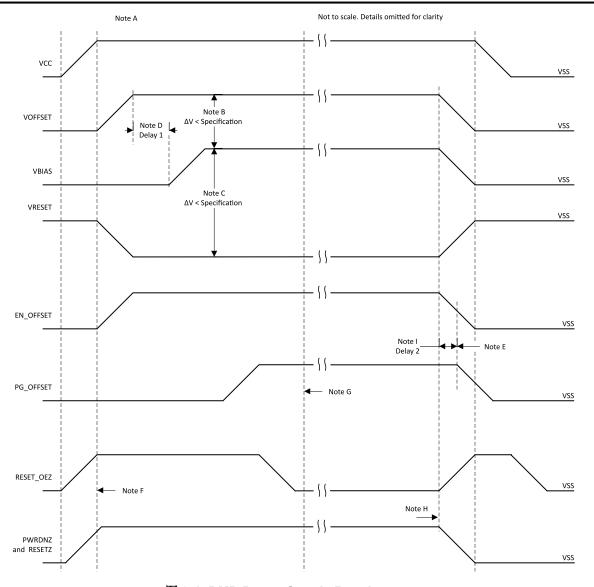


图 9-1. DMD Power Supply Requirements

- A. See 节 6.4, and the Pin Functions 表 5-1.
- B. To prevent excess current, the supply voltage difference |VOFFSET VBIAS| must be less than the specified limit in the # 6.4
- C. To prevent excess current, the supply difference |VBIAS VRESET| must be less than the specified limit in the  $\ddagger$  6.4.
- D. VBIAS must power up after VOFFSET has powered up, per the Delay1 specification in 表 9-1.
- E. PG\_OFFSET must turn off after EN\_OFFSET has turned off, per the Delay2 specification in 表 9-1.
- F. DLP® controller software enables the DMD power supplies VBIAS, VRESET, VOFFSET with VCC active after RESET\_OEZ is at logic high.
- G. DLP® controller software initiates the global VBIAS command.
- H. After the DMD micromirror park sequence is complete, the DLP® controller software initiates a hardware power-down that activates PWRDNZ and disables VBIAS, VRESET, and VOFFSET.
- I. Under power-loss conditions where emergency DMD micromirror park procedures are being enacted by the DLP® controller hardware, EN\_OFFSET may turn off after PG\_OFFSET has turned off. The OEZ signal goes high prior to PG\_OFFSET turning off to indicate the DMD micromirror has completed the emergency park procedures.

Submit Document Feedback

表 9-1. DMD Power-Supply Requirements

PARAMETER	DESCRIPTION	MIN	NOM	MAX	UNIT
Delay1	Delay from VOFFSET settled at recommended operating voltage to VBIAS power up	1	2		ms
Delay2	PG_OFFSET hold time after EN_OFFSET goes low	100			ns

## 9.3 Restrictions on Hot Plugging and Hot Swapping

The DLP500YX uses a state of the art pixel node which enables smaller optics, higher resolution, and overall great performance and reliability as long as certain design-for-assembly methods are used. To maximize DMD reliability, Hot Plugging and/or Hot Swapping DMDs voids the DMD warranty conditions and must be avoided at all times.

# 9.3.1 No Hot Plugging

Avoid hot plugging, the act of connecting the DMD to power supplies and/or data inputs which are already energized, to ensure maximum reliability of the DMD. Do not add or remove the DMD from a DMD socket unless all input power supplies of the DMD are at a potential equal to the local ground potential (VSS). This applies to a DMD incoming test station, a partially assembled product, a completed product under test, and a product in the field. This also applies to any cables, flex cables, or PCB connections which provide power to the DMD. Provide power as defined in the power-up scenario detailed in † 9.1. Perform power down as defined in † 9.2.

## 9.3.2 No Hot Swapping

Avoid hot swapping, the act of removing and replacing the DMD with DMD power supplies and/or data inputs which are already energized, to ensure maximum reliability of the DMD. Never add or remove the DMD from a DMD socket unless all input power supplies of the DMD are at a potential equal to the local ground potential (VSS). This applies to a DMD incoming test station, a partially assembled product, a completed product under test, and a product in the field. This also applies to any cables, flex cables, or PCB connections which provide power to the DMD. Provide power as defined in the power-up scenario detailed in 节 9.1. Perform power down as defined in 节 9.2

## 9.3.3 Intermittent or Voltage Power Spike Avoidance

When DMD power and/or data and clock inputs are energized, twisting of the DMD, DMD socket, or DMD board must be avoided when trying to align the DMD within an optical engine. This twisting motion can create power intermittences and/or voltage spikes exceeding input power and data specifications of the DMD which may ultimately affect the DMD reliability. PCB power/data/clock/control circuits must be de-energized before making or removing connections, including cables, connectors, probes and bed-of-nails connections.

PCB and System design considerations must take into account ways to prevent external influence of DMD input power clock, data and control signals. Robust connectors must be used which are resistant to intermittent connections or noise spikes if jostled or vibrated. Connectors must be used which are rated to exceed the number of insertion/removal cycles expected in the application. External electromagnetic emitters must not be placed nearby these sensitive circuits unless adequate EMI shielding is properly used. Sufficient bulk decoupling and component decoupling capacitance as well as appropriate PCB layout techniques must be available for all electrical components within the DMD based "system" such that ground bounce does not occur. See the section on † 10.1 for more layout information.

# 10 Layout

## 10.1 Layout Guidelines

### 10.1.1 Critical Signal Guidelines

The DLP500YX DMD is one device in a chipset controlled by the DLPC900 Controller. The following guidelines are targeted at designing a functioning PCB using this DLP500YX DMD chipset. The DLP500YX DMD board must be a high-speed multi-layer PCB containing high-speed digital logic utilizing dual edge (DDR) LVDS signals at 400 MHz clock rates. 

10-1 shows the DLP500YX signals and the recommendations needed from/to the DLPC900 Controller devices. The DLPC900 device provides the data and control to the DMD. The TPS65145 and LP38513 devices supply power to the DMD.



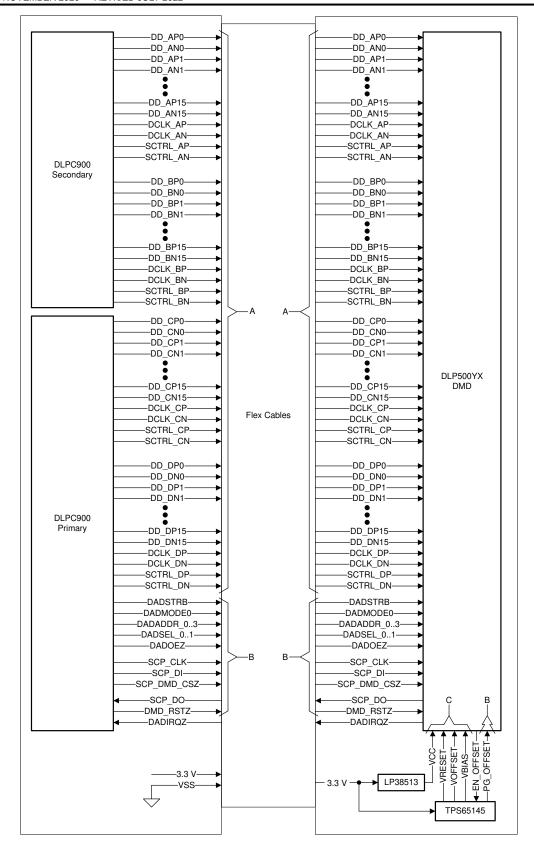


图 10-1. DLP500YX DMD System Connections and Layout Restrictions

Instruments www.ti.com.cn

# 表 10-1. Layout Restriction Notes for 图 10-1

Note	Signal Type	Guideline
	Differential	Prevent signal noise
		Route 100 ±10- Ω resistor
		Intra-pair (P-to-N) length tolerance is ±12-mils
A		DD and SCTRL must be matched to the DCLK within ±150-mils
^		DCLK_C must be matched to DCLK_D within ±1.25-ns
		DCLK_A must be matched to DCLK_B within ±1.25-ns
		Do not switch routing layers except at the beginning and end of trace
		Signal routing length must not exceed 375-mm
	Single-ended	Prevent signal noise
В		Route single-ended signals 50 ±5- $\Omega$
		No length match requirement
С	Power	VRESET, VOFFSET, VBIAS, and VCC at the DMD must be kept within the operating limits specified in the data sheet
		Provide proper amount of decoupling capacitance for each voltage at the DMD

#### 10.1.2 Power Connection Guidelines

The following are recommendations for the power connections to the DMD or DMD PCB:

- Solid planes are **required** for DMD P3P3V(3.3V), DMD P1P8V and Ground.
- TI strongly recommends partial power planes are used for VOFFSET, VRESET, and VBIAS.
- VOFFSET, VBIAS, VRESET, VCC, and VCCI power rails must be kept within the specified operating range. This includes effects from ripple and DC error.
- To accommodate power supply transient current requirements, adequate decoupling capacitance must be placed as near the DMD VOFFSET, VBIAS, VRESET, VCC, and VCCI pins as possible.
- Do not swap DMDs while the DMD is still powered on (this is called hot swapping). All DMD power supply rails and signals must be 0 volts (not driven) before connecting or disconnecting the DMD physical interface.
- Do not allow power to be applied to the DMD when one or more signal pins are not being driven.
- Decoupling capacitor locations for the DMD must be as close as possible to the DMD. The pads of the capacitors must be connected to at least two or three vias to get a very low impedance to ground as shown in 🗵 10-3. Furthermore, the capacitor must be in the flow of the power trace as it goes to the input of the DMD.
- It is extremely important to adhere to the 节 9.1 and 节 9.2 and do not allow the DMD power-supply levels to be outside of the recommended operating conditions specified in the DMD data sheet.

These figures show examples of bypass decoupling capacitor layout.

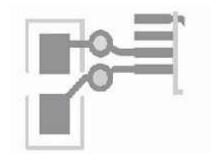


图 10-2. Poor Layout

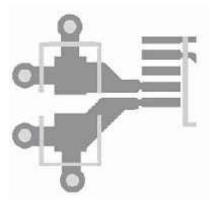


图 10-3. Good Layout



## 10.1.3 Noise Coupling Avoidance

During operation, it is critical to prevent the coupling of noise or intermittent power connections onto the following signals because *irreversible DMD micromirror array damage* or lesser effects of image disruption can occur:

- · SCTRL DN, STRL DP
- DCLK\_DN, DCLK\_DP
- SCPCLK
- SCPDI
- SCP DMD CSZ
- DADADDR\_0, DADADDR1\_1, DADADDR\_2, DADADDR\_3
- DADMODE0
- DADSEL\_0, DADSEL\_1, DADSEL\_2, DADSEL\_3
- DADSTRB
- DMD RSTZ
- DADOEZ
- PG\_OFFSET

In this context, the following conditions are considered noise:

- Shorting to another signal
- · Shorting to power
- · Shorting to ground
- Intermittent connection (includes hot swapping)
- · An electrical open condition
- · An electrical floating condition
- · Inducing electromagnetic interference that is strong enough to affect the integrity of the signals
- · Unstable inputs (conditions outside of the specified operating range) to any of the device power rails
- · Voltage fluctuations on the device ground pins

## 10.2 Layout Example

## 10.2.1 Layers

The layer stack-up and copper weight for each layer is shown in 表 10-2. Small sub-planes are allowed on signal routing layers to connect components to major sub-planes on top/bottom layers if necessary.

表 10-2. Layer Stack-Up

LAYER NO.	LAYER NAME	COPPER WT. (oz.)	COMMENTS			
1	Side A - DMD only	1.5	DMD, escapes, low frequency signals, power sub-planes.			
2	Ground	1	Solid ground plane (net GND).			
3	Signal	0.5	50 $^{\Omega}$ and 100 $^{\Omega}$ differential signals			
4	Ground	1	Solid ground plane (net GND)			
5	DMD_P3P3V	1	+3.3-V power plane (net DMD_P3P3V)			
6	Signal	0.5	50 $\Omega$ and 100 $\Omega$ differential signals			
7	Ground	1	Solid ground plane (net GND).			
8	Side B - All other Components	1.5	Discrete components, low frequency signals, power sub-planes			

Product Folder Links: DLP500YX

## 10.2.2 Impedance Requirements

TI recommends that the board has matched impedance of 50  $\,^{\Omega}$  ±10% for all signals. The exceptions are listed in  $\,^{\boxtimes}$  10-1 and repeated for convenience in  $\,^{\gtrless}$  10-3.

表 10-3. Special Impedance Requirements

Signal Type	Signal Name	Impedance (ohms)	
	D_AP(0:15), D_AN(0:15)	100 100/ 115	
A channel LVDS differential pairs	DCLK_AP, DCLK_AN	100 ±10% differential across each pair	
	SCTRL_AP, SCTRL_AN		
	D_BP(0:15), D_BN(0:15)		
B channel LVDS differential pairs	DCLK_BP, DCLK_BN	100 ±10% differential across each pair	
	SCTRL_BP, SCTRL_BN		
	D_CP(0:15), D_CN(0:15)		
C channel LVDS differential pairs	DCLK_CP, DCLK_CN	100 ±10% differential across each pair	
	SCTRL_CP, SCTRL_CN		
	D_DP(0:15), D_DN(0:15)		
D channel LVDS differential pairs	DCLK_DP, DCLK_DN	100 ±10% differential across each pair	
	SCTRL_DP, SCTRL_DN		

# 10.2.3 Trace Width, Spacing

Unless otherwise specified, TI recommends that all signals follow the 0.005" /0.005" design rule. Minimum trace clearance from the ground ring around the PWB has a 0.1" minimum. An analysis of impedance and stack-up requirements determine the actual trace widths and clearances.

# 10.2.3.1 Voltage Signals

Below are additional voltage supply layout examples from the power planes to the individual DMD pins. In general, power supply trace widths must be as wide as possible to reduce impedances.

表 10-4. Special Trace Widths, Spacing Requirements

SIGNAL NAME	MINIMUM TRACE WIDTH TO PINS (MIL)	LAYOUT REQUIREMENT		
GND	15	Maximize trace width to connecting pin		
DMD_P3P3V	15	Maximize trace width to connecting pin		
DMD_P1P8V	15	Maximize trace width to connecting pin		
VOFFSET	15	Create mini plane from the power generation to the DMD input		
VRESET	15	Create mini plane from the power generation to the DMD input		
VBIAS	15	Create mini plane from the power generation to the DMD input		
All DMD control input/ output connections	10	Use 10 mil etch to connect all signals/voltages to DMD pads		



# 11 Device and Documentation Support

# 11.1 第三方产品免责声明

TI 发布的与第三方产品或服务有关的信息,不能构成与此类产品或服务或保修的适用性有关的认可,不能构成此类产品或服务单独或与任何 TI 产品或服务一起的表示或认可。

## 11.2 Device Support

#### 11.2.1 Device Nomenclature

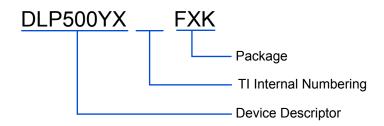


图 11-1. Part Number Description

## 11.2.2 Device Markings

The device marking includes both human-readable information and a 2-dimensional matrix code. The human-readable information is described in [8] 11-2. The 2-dimensional matrix code is an alpha-numeric character string that contains the DMD part number, part 1 of the serial number, and part 2 of the serial number. The first character of the DMD serial number (part 1) is the manufacturing year. The second character of the DMD serial number (part 1) is the manufacturing month.

Example: DLP500YXFXK GHXXXXX LLLLLLM

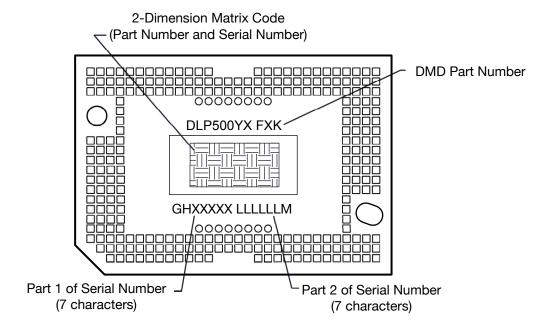


图 11-2. DMD Marking Locations

Submit Document Feedback

# 11.3 Documentation Support

### 11.3.1 Related Documentation

The following documents contain additional information related to the chipset components used with the DLP500YX.

- DLP500YX Product Folder
- DLPC900 Product Folder
- DLPC900 Programmers Guide

# 11.4 接收文档更新通知

要接收文档更新通知,请导航至 ti.com 上的器件产品文件夹。点击*订阅更新* 进行注册,即可每周接收产品信息更改摘要。有关更改的详细信息,请查看任何已修订文档中包含的修订历史记录。

# 11.5 支持资源

TI E2E™ 支持论坛是工程师的重要参考资料,可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者"按原样"提供。这些内容并不构成 TI 技术规范,并且不一定反映 TI 的观点;请参阅 TI 的《使用条款》。

### 11.6 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments.

DLP® is a registered trademark of Texas Instruments.

所有商标均为其各自所有者的财产。

# 11.7 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 11.8 术语表

TI 术语表

本术语表列出并解释了术语、首字母缩略词和定义。



# 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

www.ti.com 2-May-2025

#### PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
DLP500YXFXK	Last Time Buy	Production	CLGA (FXK)   257	33   JEDEC TRAY (5+1)	Yes	NI-PD-AU	N/A for Pkg Type	0 to 70	

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

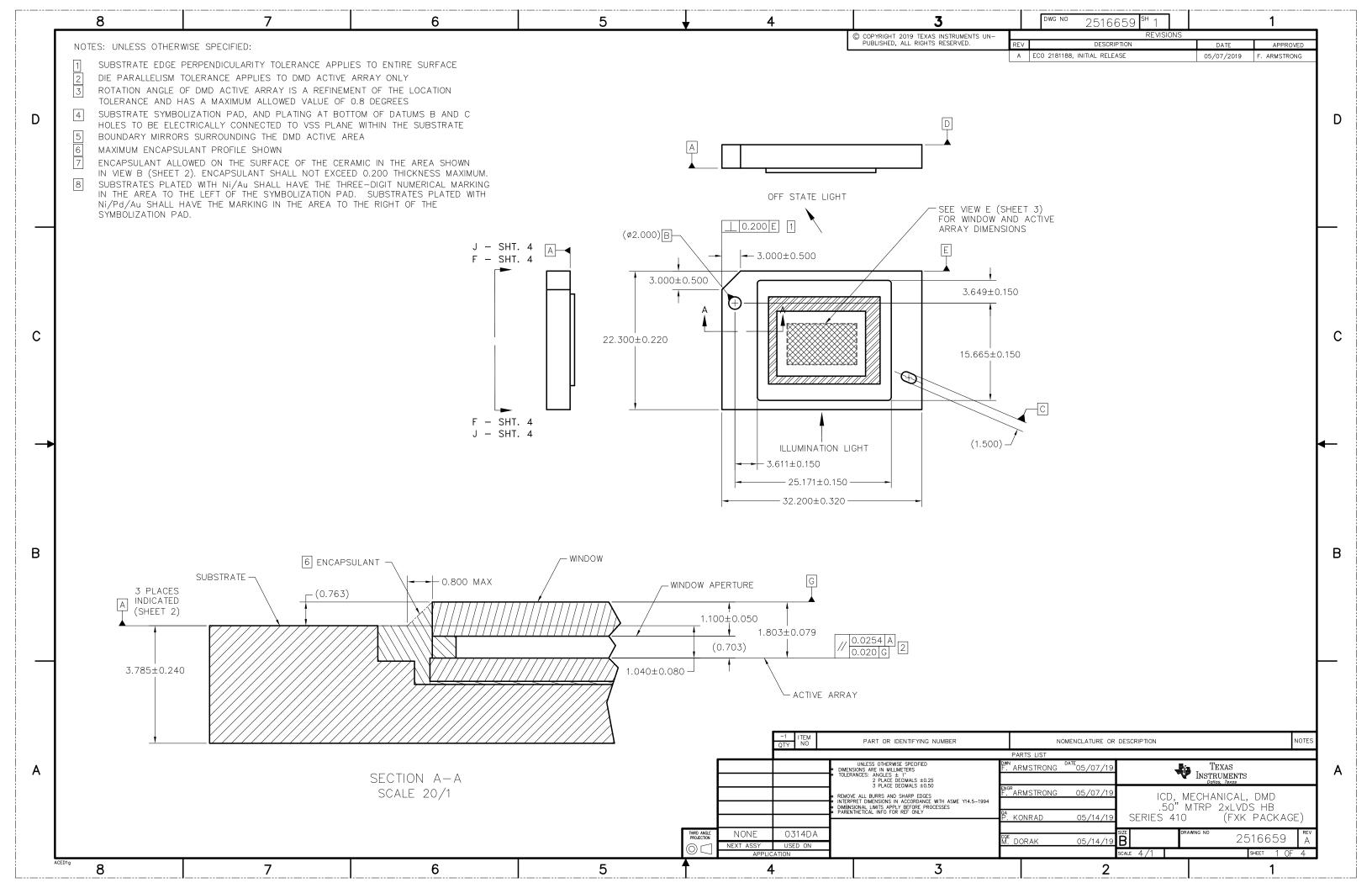
<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

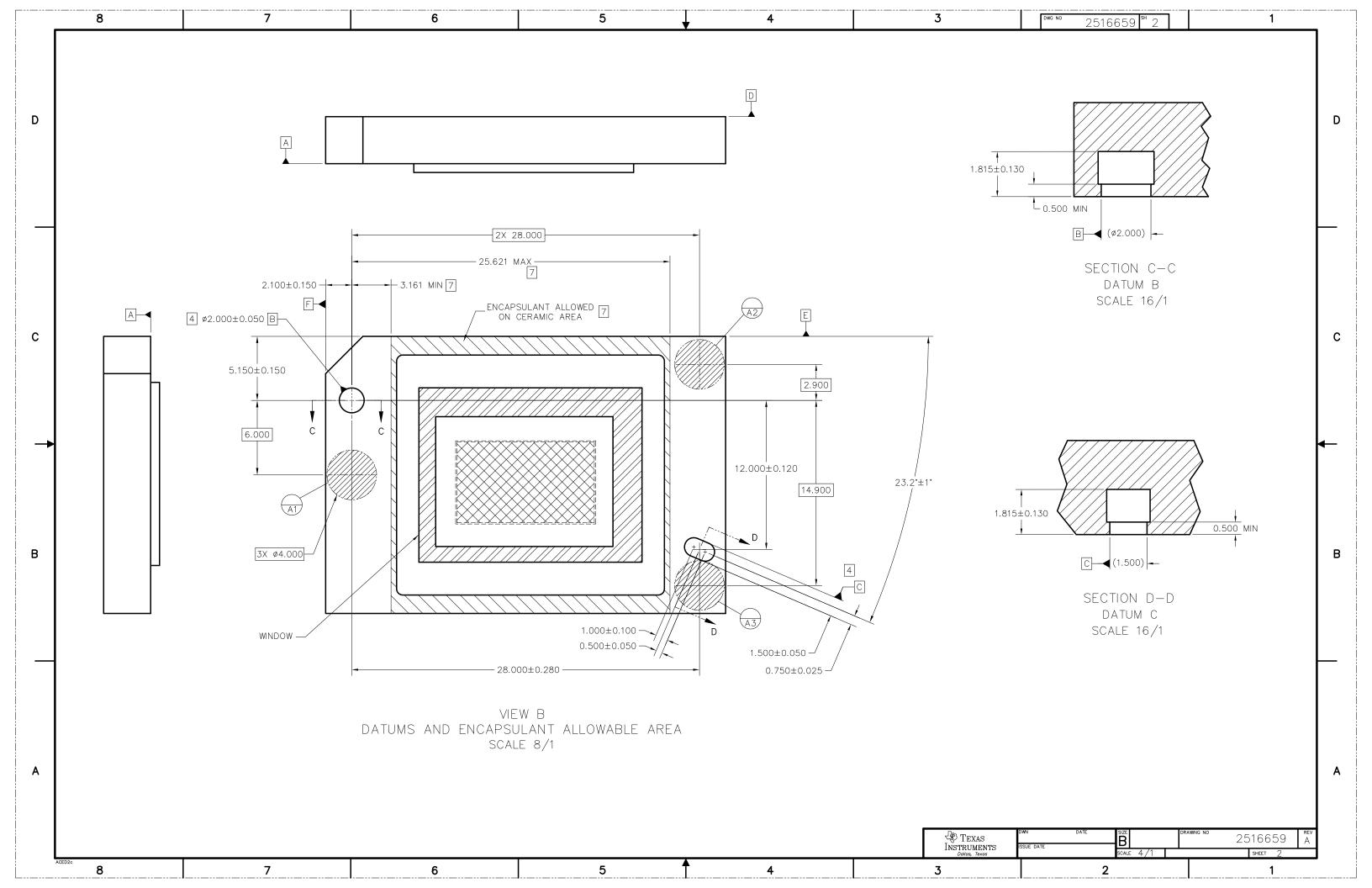
<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

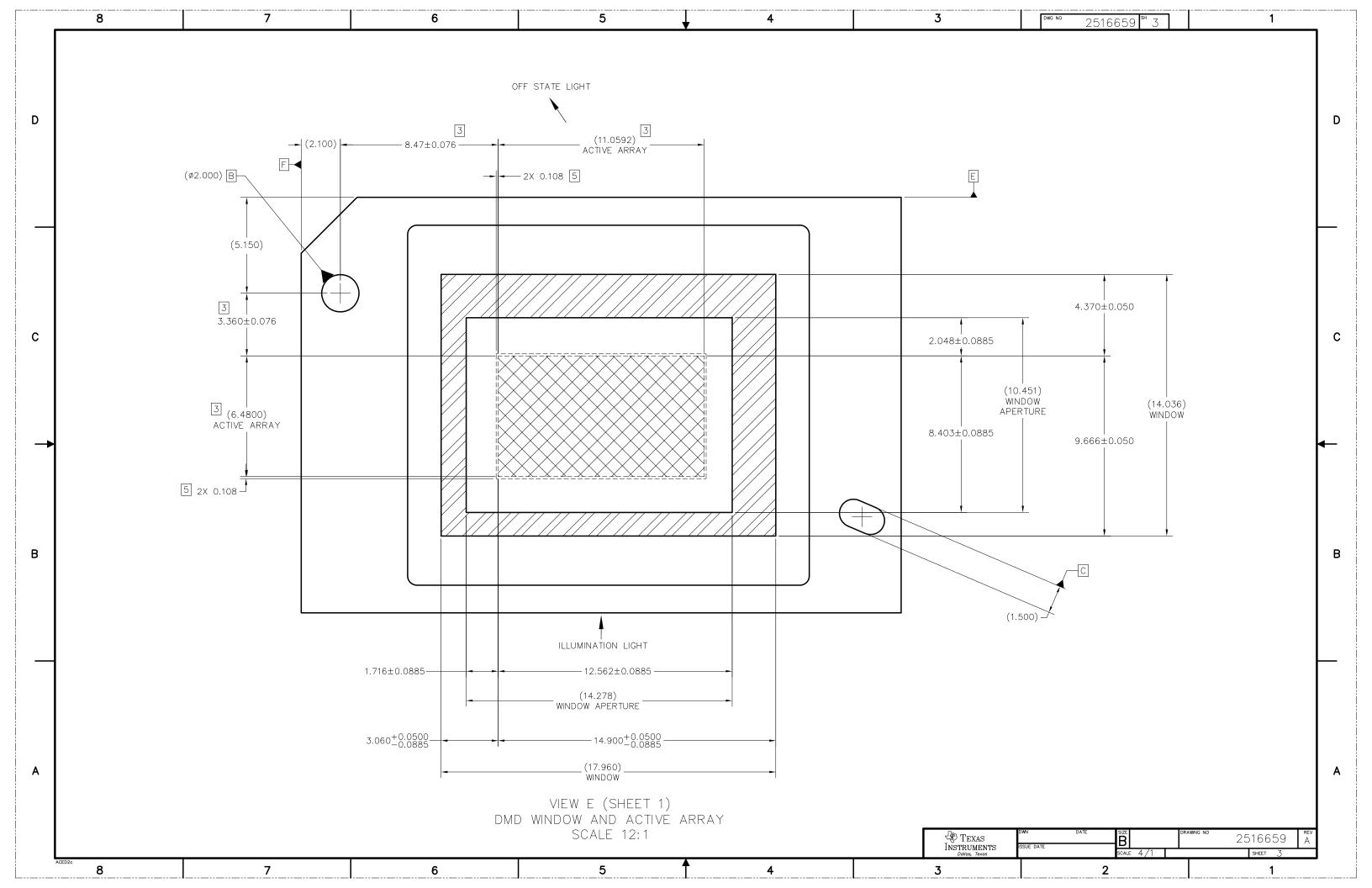
<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

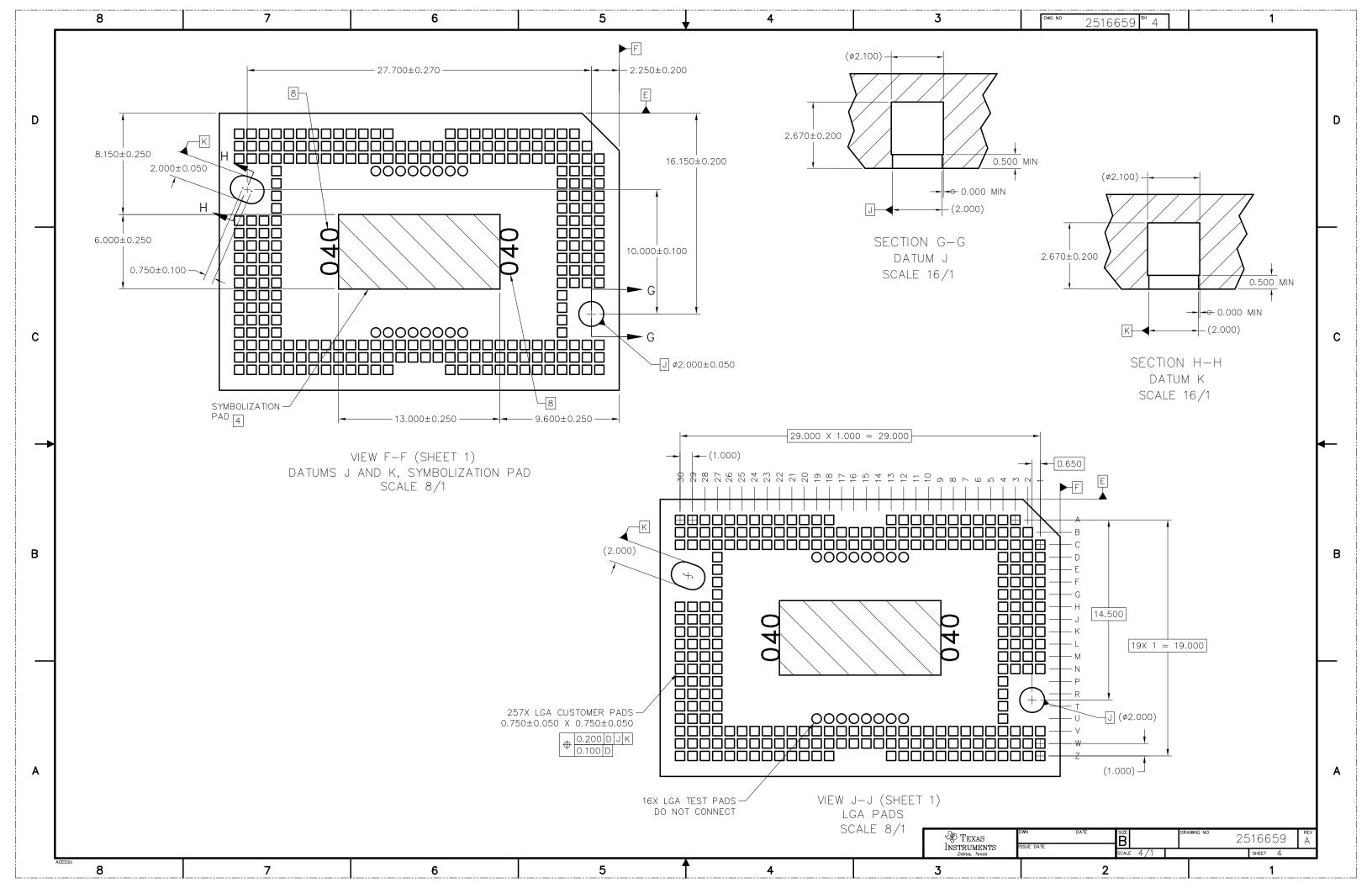
<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.









# 重要通知和免责声明

TI"按原样"提供技术和可靠性数据(包括数据表)、设计资源(包括参考设计)、应用或其他设计建议、网络工具、安全信息和其他资源,不保证没有瑕疵且不做出任何明示或暗示的担保,包括但不限于对适销性、某特定用途方面的适用性或不侵犯任何第三方知识产权的暗示担保。

这些资源可供使用 TI 产品进行设计的熟练开发人员使用。您将自行承担以下全部责任:(1) 针对您的应用选择合适的 TI 产品,(2) 设计、验证并测试您的应用,(3) 确保您的应用满足相应标准以及任何其他功能安全、信息安全、监管或其他要求。

这些资源如有变更,恕不另行通知。TI 授权您仅可将这些资源用于研发本资源所述的 TI 产品的相关应用。 严禁以其他方式对这些资源进行复制或展示。您无权使用任何其他 TI 知识产权或任何第三方知识产权。您应全额赔偿因在这些资源的使用中对 TI 及其代表造成的任何索赔、损害、成本、损失和债务,TI 对此概不负责。

TI 提供的产品受 TI 的销售条款或 ti.com 上其他适用条款/TI 产品随附的其他适用条款的约束。TI 提供这些资源并不会扩展或以其他方式更改 TI 针对 TI 产品发布的适用的担保或担保免责声明。

TI 反对并拒绝您可能提出的任何其他或不同的条款。

邮寄地址:Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 版权所有 © 2025,德州仪器 (TI) 公司